

FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)		APPLICANT(S): MORICEAU, et al.

**REFERENCE DESIGNATION U.S. PATENT DOCUMENTS**

EXAMINER INITIAL		DOCUMENT NUMBER <small>Number-Kind Code (if known)</small>	DATE	NAME	CLASS/ SUBCLASS	FILING DATE
	E1	3,901,423	08/1975	Hillberry, et al.		
	E2	3,915,757	10/1975	Engel		
	E3	3,957,107	05/1976	Altoz et al.		
	E4	3,993,909	11/1976	Drews et al.		
	E5	4,006,340	02/1977	Gorinas		
	E6	4,028,149	06/1977	Deines et al.		
	E7	4,039,416	08/1977	White		
	E8	4,074,139	02/1978	Pankove		
	E9	4,107,350	08/1978	Berg et al.		
	E10	4,108,751	08/1978	King		
	E11	4,121,334	10/1978	Wallis		
	E12	4,170,662	10/1979	Weiss et al.		
	E13	4,179,324	12/1979	Kirkpatrick		
	E14	4,244,348	01/1981	Wilkes		
	E15	4,252,837	02/1981	Auton		
	E16	4,254,590	03/1981	Eisele et al.		
	E17	4,274,004	06/1981	Kanai		
	E18	4,324,631	08/1982	White et al.		
	E19	4,346,123	08/1982	Kaufmann		
	E20	4,361,600	11/1982	Brown		
	E21	4,368,083	01/1983	Bruel et al.		
	E22	4,412,868	11/1983	Brown et al.		
	E23	4,452,644	06/1984	Bruel et al.		
	E24	4,468,309	08/1984	White		
	E25	4,471,003	09/1984	Cann		
	E26	4,486,247	12/1984	Ecer et al.		
	E27	4,490,190	12/1984	Speri		
	E28	4,500,563	02/1985	Ellenberger et al.		
	E29	4,508,056	04/1985	Bruel et al.		
	E30	4,536,657	08/1985	Bruel		
	E31	4,539,050	09/1985	Kramler et al.		
	E32	4,542,863	09/1985	Larson		
	E33	4,566,403	01/1986	Fournier		

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	E34 4,567,505	01/1986	Pease		
	E35 4,568,563	02/1986	Jackson et al.		
	E36 4,585,945	04/1986	Bruel et al.		
	E37 4,630,093	12/1986	Yamaguchi et al.		
	E38 4,684,535	08/1987	Heinecke et al.		
	E39 4,704,302	11/1987	Bruel et al.		
	E40 4,717,683	01/1988	Parrillo et al.		
	E41 4,764,394	08/1988	Conrad		
	E42 4,837,172	06/1989	Mizuno et al.		
	E43 4,846,928	07/1989	Dolins et al.		
	E44 4,847,792	07/1989	Barna et al.		
	E45 4,853,250	08/1989	Boulos et al.		
	E46 4,887,005	12/1989	Rough et al.		
	E47 4,894,709	01/1990	Phillips et al.		
	E48 4,904,610	02/1990	Shyr		
	E49 4,920,396	04/1990	Shinohara et al.		
	E50 4,929,566	05/1990	Beitman		
	E51 4,931,405	06/1990	Kamijo et al.		
	E52 4,948,458	08/1990	Ogle		
	E53 4,952,273	08/1990	Popov		
	E54 4,956,698	09/1990	Wang		
	E55 4,960,073	10/1990	Suzuki et al.		
	E56 4,975,126	12/1990	Margail et al.		
	E57 4,982,090	01/1991	Wittmaack		
	E58 4,996,077	02/1991	Moslehi et al.		
	E59 5,013,681	05/1991	Godbey et al.		
	E60 5,015,353	05/1991	Hubler et al.		
	E61 5,034,343	07/1991	Rouse et al.		
	E62 5,036,023	07/1991	Dautremont-Smith et al.		
	E63 5,110,748	05/1992	Sarna		
	E64 5,120,666	06/1992	Gotou		
	E65 5,138,422	08/1992	Fujii et al.		
	E66 5,198,371	03/1993	Li		
	E67 5,200,805	08/1993	Parsons et al.		
	E68 5,232,870	08/1993	Ito et al.		
	E69 5,234,535	08/1993	Beyer et al.		
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	E70 5,242,863	09/1993	Xiang-Zheng et al.		
	E71 5,250,446	10/1993	Osawa et al.		
	E72 5,256,581	10/1993	Foerstner et al.		
	E73 5,300,788	04/1994	Fan et al.		
	E74 5,310,446	05/1994	Konishi et al.		
	E75 5,400,458	03/1995	Rambosek		
	E76 5,405,802	04/1995	Yamagata et al.		
	E77 5,413,951	05/1995	Ohori et al.		
	E78 5,494,835	02/1996	Bruel		
	E79 5,524,339	06/1996	Gorowitz et al.		
	E80 5,559,043	09/1996	Bruel		
	E81 5,567,654	10/1996	Beilstein, Jr. et al.		
	E82 5,611,316	03/1997	Oshima et al.		
	E83 5,618,739	04/1997	Takahashi et al.		
	E84 5,622,896	04/1997	Knotter et al.		
	E85 5,633,174	05/1997	Li		
	E86 5,661,333	08/1997	Bruel et al.		
	E87 5,714,395	02/1998	Bruel		
	E88 5,804,086	09/1998	Bruel		
	E89 5,811,348	09/1998	Matushita et al.		
	E90 5,817,368	10/1998	Hashimoto		
	E91 5,854,123	12/1998	Sato et al.		
	E92 5,863,830	01/1999	Bruel et al.		
	E93 5,863,832	01/1999	Doyle et al.		
	E94 5,877,070	03/1999	Goesele et al.		
	E95 5,882,987	03/1999	Srikrishnan		
	E96 5,897,331	04/1999	Sopori		
	E97 5,909,627	06/1999	Egloff		
	E98 5,920,764	07/1999	Hanson et al.		
	E99 5,953,622	09/1999	Lee et al.		
	E100 5,966,620	10/1999	Sakaguchi et al.		
	E101 5,981,400	11/1999	Lo		
	E102 5,985,412	11/1999	Gösele		
	E103 5,993,677	11/1999	Biasse et al.		
	E104 5,994,207	11/1999	Henley et al.		
	E105 6,010,591	01/2000	Gösele		
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EXAMINER INITIAL	DOCUMENT NUMBER <small>Number-Kind Code (if known)</small>	DATE	NAME	CLASS/ SUBCLASS	FILING DATE
	E106 6,013,563	01/2000	Henley et al.		
	E107 6,013,954	01/2000	Hamajima		
	E108 6,020,252	02/2000	Aspar et al.		
	E109 6,033,974	03/2000	Henley et al.		
	E110 6,048,411	04/2000	Henley et al.		
	E111 6,054,363	04/2000	Sakaguchi et al.		
	E112 6,054,370	04/2000	Doyle		
	E113 6,057,212	05/2000	Chan et al.		
	E114 6,071,795	06/2000	Cheung et al.		
	E115 6,096,433	08/2000	Kikuchi et al.		
	E116 6,103,597	08/2000	Aspar et al.		
	E117 6,103,599	08/2000	Henley et al.		
	E118 6,118,181	09/2000	Merchant et al.		
	E119 6,127,199	10/2000	Inoue		
	E120 6,146,979	11/2000	Henley et al.		
	E121 6,150,239	11/2000	Goesele et al.		
	E122 6,159,323	12/2000	Joly et al.		
	E123 6,190,998	02/2001	Bruel et al.		
	E124 6,200,878	03/2001	Yamagata et al.		
	E125 6,204,079	03/2001	Aspar et al.		
	E126 6,225,190	05/2001	Bruel et al.		
	E127 6,225,192	05/2001	Aspar et al.		
	E128 6,271,101	08/2001	Fukunaga		
	E129 6,294,478	09/2001	Shkaguchi et al.		
	E130 6,303,468	10/2001	Aspar et al.		
	E131 6,316,333	11/2001	Bruel et al.		
	E132 6,323,108	11/2001	Kub et al.		
	E133 6,323,109	11/2001	Okonogi		
	E134 6,346,458	02/2002	Bower		
	E135 6,362,077	03/2002	Aspar et al.		
	E136 6,362,082	03/2002	Doyle et al.		
	E137 6,429,104	03/2002	Auberton-Herve		
	E138 6,513,564	02/2003	Bryan et al.		
	E139 6,534,380	03/2003	Yamauchi et al.		
	E140 6,593,212	07/2003	Kub et al.		
	E141 2001/0007367	07/2001	Ohkubo		
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EXAMINER INITIAL		DOCUMENT NUMBER <small>Number-Kind Code (if known)</small>	DATE	NAME	CLASS/ SUBCLASS	FILING DATE
	E142	2001/0007789 A1	07/2001	Aspar et al.		
	E143	2002/0025604	02/2002	Tiwari		
	E144	2002/0153563	10/2002	Ogura		
	E145	2002/0185684 A1	12/2002	Campbell et al.		
	E146	2002/083387 A1	06/2002	Miner et al.		
	E147	2003/0119279 A1	06/2003	Enquist		
	E148	2003/0134489	07/2003	Schwarzenbach et al.		

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## FOREIGN PATENT DOCUMENTS

EXAMINER INITIAL		DOCUMENT NUMBER <small>Number-Kind Code (if known)</small>	DATE	COUNTRY	CLASS/ SUBCLASS	TRANSLATION YES OR NO
	E149	EP 0 293 049 B1	09/1993	EUROPE		
	E150	EP 0 355 913	02/1990	EUROPE		
	E151	EP 0 410 679 A1	01/1991	EUROPE		
	E152	EP 0 504 714	09/1992	EUROPE		
	E153	EP 0 533 551 A1	03/1993	EUROPE		
	E154	EP 0 660 140	06/1995	EUROPE		
	E155	EP 0 665 588 A1	08/1995	EUROPE		
	E156	EP 0 703 609	03/1996	EUROPE		
	E157	EP 0 717 437 B1	04/2002	EUROPE		
	E158	EP 0 786 801 A1	06/2003	EUROPE		
	E159	EP 0 793 263 A2	09/1997	EUROPE		
	E160	EP 0 801 419 A1	10/1997	EUROPE		
	E161	EP 0 807 970 A1	11/1997	EUROPE		
	E162	EP 0 849 788 A2	06/1998	EUROPE		
	E163	EP 0 889 509 A2	01/1999	EUROPE		
	E164	EP 0 898 307	02/1999	EUROPE		
	E165	EP 0 902 843 B1	03/2000	EUROPE		
	E166	EP 0 917 193 A1	05/1999	EUROPE		
	E167	EP 0 938 129 A1	08/1999	EUROPE		
	E168	EP 0 989 593 A2	03/2000	EUROPE		
	E169	EP 0 994 503 A1	04/2000	EUROPE		
	E170	EP 1 050 901 A2	11/2000	EUROPE		
	E171	EP 1 059 663 A2	12/2000	EUROPE		
	E172	FR 2 671 472 A1	07/1992	FRANCE		
	E173	FR 2 725 074	03/1996	FRANCE		
	E174	FR 2 748 850 A1	11/1997	FRANCE		
	E175	FR 2 748 851	11/1997	FRANCE		
	E176	FR 2 758 907 A1	07/1998	FRANCE		
	E177	FR 2 767 416 A1	02/1999	FRANCE		
	E178	FR 2 767 604	02/1999	FRANCE		
	E179	FR 2 771 852 A1	06/1999	FRANCE		
	E180	FR 2 773 261	07/1999	FRANCE		
	E181	FR 2 774 510 A1	08/1999	FRANCE		
	E182	FR 2 781 925 A1	02/2000	FRANCE		
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	E183 FR 2 796 491	01/2001	FRANCE		
	E184 FR 2 809 867	12/2001	FRANCE		
	E185 FR 2 819 099 A1	07/2002	FRANCE		
	E186 GB 2 211 991 A	07/1989	GREAT BRITAIN		
	E187 JP 53-104156	09/1978	JAPAN		
	E188 JP 59-54217	03/1984	JAPAN		
	E189 JP 62265717	11/1987	JAPAN		
	E190 JP 101004013	01/1989	JAPAN		
	E191 JP 07-254690	10/1995	JAPAN		
	E192 JP 7-302889	11/1995	JAPAN		
	E193 JP 09-213594	08/1997	JAPAN		
	E194 JP 09-307719	11/1997	JAPAN		
	E195 JP 11045862	02/1999	JAPAN		
	E196 JP 11087668	03/1999	JAPAN		
	E197 JP 11074208	03/1999	JAPAN		
	E198 JP 11-145436	05/1999	JAPAN		
	E199 JP 10163166	06/1998	JAPAN		
	E200 JP 8133878	05/1996	JAPAN		
	E201 JP 10233352	09/1998	JAPAN		
	E202 JP 11317577	11/1999	JAPAN		
	E203 JP 4199504	07/1992	JAPAN		
	E204 JP 08017777	01/1990	JAPAN		
	E205 JP 58 31519	02/1983	JAPAN		
	E206 RU 128757	06/2000	RUSSIA		
	E207 WO 95/20824 A1	08/1995	PCT		
	E208 WO 99/08316 A1	02/1999	PCT		
	E209 WO 99/35674 A1	07/1999	PCT		
	E210 WO 99/39378 A1	08/1999	PCT		
	E211 WO 00/48238 A1	08/2000	PCT		
	E212 WO 00/63965 A1	10/2000	PCT		
	E213 WO 01/11930 A2	02/2001	PCT		
	E214 WO 01/43168 A2	06/2001	PCT		
	E215 WO 02/05344 A1	01/2002	PCT		
	E216 WO 02/47156 A1	06/2002	PCT		
	E217 WO 02/083387 A1	10/2002	PCT		
	E218 WO 03/013815 A1	02/2003	PCT		

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EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E215	Agarwal et al., "Efficient Production of Silicon-On-Insulator Films by Co-Implantation of HE+ with H+", <i>Applied Physics Letters</i> , Vol. 72, No. 9, 1988, pp 1086-1088.
E216	Agarwal, Aditya et al. "Efficient Production of Silicon-On-Insulator Films by Co-Implantation of He+ with H" – Proceedings 1997 IEEE International SOI Conference, October 1997 – pp. 44-45.
E217	Ahn, K. Y., et al., "Growth, Shrinkage, And Stability of Interfacial Oxide Layers Between Directly Bonded Silicon Wafers", <i>Applied Physics A</i> , Vol. 50, 1990, pp 85-94.
E218	Almedia et al. "Bond formation in ion beam synthesized amorphous gallium nitride", <i>Elsevier, Thin Solid Films</i> , 343-344 1999, pp 632-636.
E219	Ascheron, C., "A Comparative Study of Swelling, Radiation, Strain and Radiation Damage of High-Energy Proton-bombarded GaAs, GaP, InP, Si and Ge Single Crystals, Nuclear Instruments and Methods in Physics Research", <i>Nuclear Instruments and Methods in Physics Research B36</i> , (1989), 1637172.
E220	Ascheron, C., "A Study of Proton Bombardment Induced Swelling of GaP Single Crystals", <i>Phys. stat. sol. (a)</i> 92, (1985), pp 169.
E221	Ascheron, C., "Gettering a Copper in Proton-and Helium-Bombarded Buried Regions of Gallium Phosphide", <i>Phys. stat. sol. (a)</i> , Vol. 106, 1988, pp 73-79.
E222	Ascheron, C., "Investigations of Hydrogen Implanted GaP Single Crystals by Means of Particle Induced 7-Spectroscopy, Infrared Spectroscopy, and Turyherford Backscattering Channeling Technique" <i>Phys. stat. sol. (a)</i> 89, (1985), pp 549.
E223	Ascheron, C., "Proton Beam Modification of Selected AlIII BV Compounds", <i>Phys. stat. sol. (a)</i> 124, (1991), pp 11.
E224	Ascheron, C. et al, "Proton Bombardment Induced Swelling of GaP", 1985, pp. 169-176.
E225	Ascheron, C., "Swelling, Strain, and Radiation Damage of He+ Implanted GaP", <i>Phys. stat. sol. (a)</i> 96, 1986, pp. 555-562. (1986).
E226	Asheron, C., "The Effect of Hydrogen Implantation Induced Stress on GaP Single Crystals", <i>Nuclear Instruments and Methods in Physics Research</i> , B28 (1987), pp 350-359.
E227	Aspar et al., Smart-Cut®: The basic fabrication process for UNIBOND® SOI wafers, <i>SEMI</i> 1996, pp. 37-46.
E228	Aspar et al., U.S. App. No. 09/777,516, also Pub. No. US 2001/0007789 A1 with copy of allowed claims, Published July 12, 2001.
E229	Aspar, B. "Basic Mechanisms Involved in the Smart-Cut Process", 1997, pp. 223-240.

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E230	Aspar, B. et al, "Characterization of SOI substrates: Application to Recent SIMOX and UNIBOND Wafers," <i>Electrochemical Society Proceedings</i> , vol. 96-3, pp. 99-111.
E231	Aspar, B. et al, "Transfer of Structured and Patterned Thin Silicon Films Using the Smart-Cut Process", 1996, pp. 1985-1986.
E232	Aspar, B. Et al., "Ultra Thin Buried Oxide Layers Formed By Low Dose SIMOX Processes", Proc. 6 <sup>th</sup> International Conference on SOI Technology and Devices, <i>Electro. Soc.</i> , Vol. 94, No. 11, 1994, pp 62.
E233	Aspar, B. et al., "Smart Cut – Process Using Metallic Bonding: Application to Transfer of Si, GaAs, InP Thin Films", <i>Electronic Letters</i> – June 10, 1999, Vol. 35, No. 12., pp. 1024-1025.
E234	Auberton-Herve, A. J. et al, "A New Sal Material: Smart-Cut", 1996, pp.214-219.
E235	Auberton-Herve, A.J. et al, "SOI Materials for ULSI Applications", <i>Semiconductor International</i> , Oct. 1995, 5 pps.
E236	Blanchard-Lagahe C. et al., "Hydrogen and Helium Implantation to Achieve Layer Transfer" Vol. 19, pp. 346-358, 2003, <i>Semiconductor Wafer Bonding VII: Science, Technology, and Applications – Proceedings of the International Symposium</i> .
E237	Blöchl P.E. et al., "First-Principles Calculations of Diffusion Coefficients: Hydrogen in Silicon, <i>Physical Review Letters</i> , Vol. 64, No. 12, 1990, pp 1401-1404.
E238	Borgati, Stephen P., "The Root-Mean-Square", Boston College, Nov. 16, 1998, Obtained from the Internet at: < <a href="http://www.analytictech.com/mb313/rootmean.htm">http://www.analytictech.com/mb313/rootmean.htm</a> >.
E239	Bruel, M. et al., (Vol. 99-1) Meeting Abstract No. 333, "Single Crystal Semiconductor Layer Delamination and Transfer Through Hydrogen Implantation", The 195 <sup>th</sup> Meeting of the Electrochemical Society, May 2-6, 1999, Seattle, Washington.
E240	Bruel, Michel, "Application of Hydrogen Ion Beams To Silicon on Insulator Material Technology", <i>Nuclear Instruments and Methods in Physics Research</i> , B108, 1996, pp 313-319.
E241	Bruel, M. et al., "Smart-Cut: A New Silicon on Insulator Material Technology Based on Hydrogen Implantation and Wafer Bonding", 1997, pp. 1636-164, Col. 36, Part 1, No. 3B.
E242	Bruel, M. "Smart-Cut Process: The Way to Unibond S.O.I. Wafers", 1996, pages unknown.
E243	Bruel, M. et al, "Smart-Cut": A Promising New SOI material technology, <i>Proceedings 1994 IEEE, International Sal Conference</i> , Oct. 1995, pp. 178-179.
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E245	Bruel, M., "Silicon on insulator Material Technology", <i>Electronic Letters</i> ; 31 (1995) Jul. 6; No. 14; pp. 1201-1202.

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FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE July 25, 2006	GROUP ART UNIT 2812
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EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E246	Brueel, M., "Silicon-an-Insulator", <i>European Semiconductor</i> , Mar. 1997.
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E261	Cullis, A.G. et al., "Comparative study of annealed neon-, argon-, and krypton-ion implantation damage in silicon," <i>J. Appl. Phys.</i> , 49(10), Oct. 1978, pp. 5188-5198.
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E309	Miyagawa, S., "Surface structure of silicon carbide irradiated with helium ions with mono energy and continuous energy distributions" <i>J. Appl. Phys.</i> 53(12), Dec. 1982, pp. 8697-8705.
E310	Monemar, B. "Shallow Impurities in Semiconductors 1998", Proceedings of the Third International Conference in Sweden, Aug. 10-12, 1988, No. 95, pp 493-499.
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E321	Office Action (Non-Final) for Appln. Serial No. 10/468,223 – Dated 10/5/05 (15)
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E323	Office Action (Non-Final) for Appln. Serial No. 10/468,223 – Dated 01/10/07 (15)
E324	Office Action (Final) for Appln. Serial No. 10/468,223 – Dated 07/20/07 (15)
E325	Office Action (Non-Final) for Appln. Serial No. 10/468,223 – Dated 02/11/08 (15)
E326	Office Action (Final) for Appln. Serial No. 10/468,223 – Dated 10/29/08 (15)
E327	Office Action (Non-Final) for Appln. Serial No. 10/468,223 – Dated 06/25/09 (15)
E328	Office Action (Non-Final) for Appln. Serial No. 10/474,984 – Dated 09/24/04 (16)
E329	Office Action (Non-Final) for Appln. Serial No. 10/474,984 – Dated 06/06/05 (16)
E330	Office Action (Non-Final) for Appln. Serial No. 10/474,984 – Dated 11/16/05 (16)
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E331	Office Action (Non-Final) for Appln. Serial No. 10/474,984 – Dated 05/17/06 (16)
E332	Office Action (Non-Final) for Appln. Serial No. 10/474,984 – Dated 05/07/07 (16)
E333	Office Action (Non-Final) for Appln. Serial No. 10/474,984 – Dated 02/06/08 (16)
E334	Office Action (Final) for Appln. Serial No. 10/474,984 – Dated 10/17/08 (16)
E335	Office Action (Non-Final) for Appln. Serial No. 10/474,984 – Dated 07/07/09 (16)
E336	Office Action (Non-Final) for Appln. Serial No. 10/540,303 – Dated 12/18/07 (30)
E337	Office Action (Non-Final) for Appln. Serial No. 10/561,299 – Dated 03/26/08 (34)
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E339	Office Action (Final) for Appln. Serial No. 10/561,299 – Dated 05/11/09 (34)
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E356	Sioshansi, Piran, "Ion Beam Modification of Materials for Industry," <i>Thin Solid Film</i> , vol. 118, 1984, pp. 61-71.
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E366	Terreault, Bernard, "Hydrogen Blistering of Silicon: Progress In Fundamental Understanding", <i>Phys. Stat. Sol. (a)</i> 204, No. 7, 2007, pp 2129-2184.
E367	Theodore, N. David et al., "TFSOI With Improved Oxidation Resistance (To Reduce Isolation Induced Stresses and Leakage), Motorola Bulletin XP 000691920, <i>Technical Developments</i> , Nov. 1996, pp 158-59.
E368	Timoshenko, S. et al., "Analysis of Bi-Metal Thermostats", <i>J. Opt. Soc. Am.</i> , Vol. 11, 1925, pp 233-256.
E369	Tong et al., "Low Temperature Si Layer Splitting", Proceedings 1997 IEEE International SOI Conference, Oct. 1997, pp 126-127.

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EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E370	Tonini, Monelli, Corni, Ottaviani, Frabboni, Canteri, Queirolo, "Hydrogen Interaction with phosphorus ion implanted silicon", <i>Ion Implantation Technology</i> -94, (1995) pp. 801-804.
E371	Tzeng, J.C., "A Novel Self-Aligned Oxygen (Salox) Implanted SOI Mosfet Device Structure" <i>Nuclear Instruments and Methods in Physics Research B2</i> , 1987, pp. 112-115.
E372	U.S. Dept. of Energy, "The Fusion Connection: Contributions to Industry, Defense, and Basic Science Resulting From Scientific Advances Made in the Magnetic Fusion Energy Program", <i>Plasma Coating</i> , pp. 6-7, 1985.
E373	Van de Walle, C. "Structural Identification of Hydrogen and Muonium Centers in Silicon First Principles Calculations of Hyperfine Parameters", <i>Physical Review Letters</i> , Vol. 60, No. 26, 1988, pp 2761-2764.
E374	Van de Walle, C. "Theoretical Aspects of Hydrogen in Crystalline Semiconductors", <i>Physica B</i> , Holland, Vol. 170, No. 15, 1991, pp 21-32.
E375	Van de Walle, C. "Theory of Hydrogen Diffusion and Reactions in Crystalline Silicon", <i>Physical Review Letters</i> , Vol. 64, No. 6, 1980, pp 669-672.
E376	Van de Walle, C. "Theory of Hydrogen Diffusion and Reactions in Crystalline Silicon", <i>Physical Review B</i> , Vol. 39, No. 15, 1989, pp 10 791-10 808, plus diagrams.
E377	Van Swijgenhoven et al. "Helium Bubble and Blister Formation for Nickel and An AMorphous Fe-Ni-Mo-B Alloy During 5 keV He <sup>+</sup> -Irradiation at Temperatures Between 200 K and 600", <i>Nuclear Instruments and Methods</i> , 209/210, 1983, pp. 461-468.
E378	Veldkamp, W.B. et al., "Binary Optics," <i>Scientific American</i> , 1992, pp. 50-55.
E379	Venezia et al., "The Role of Implantation Damage in the Production of Silicon-On-Insulator Films By Co-Implantation Of He <sup>+</sup> and H <sup>+</sup> ", <i>Electrochemical Society Proceedings Volume 98-1</i> , 1998 - pp. 1384-1395.
E380	Weldon et al., "Mechanism Of Silicon Exfoliation Induced by Hydrogen/Helium Co-implantation", <i>Applied Physics Letters</i> , Vol. 73, No. 25, pp 3721-3723, Dec 21, 1998.
E381	Wemple, S.H., "Optical and channeling studies of ion-bombarded GaP", <i>J. Appl. Phys.</i> , vol. 45, No.4, Apr. 1974, pp 1578-1588.
E382	Whitton, J. L. et al., "The Collection of Ions Implanted In Semiconductors: 1 Saturations Effects", <i>Radiation Effects</i> , Scotland, Vol. 16, 1972, pp 101-105.
E383	Wiegand, M. et al., "Wafer Bonding of Silicon Wafers Covered With Various Surface Layers", <i>Sensors and Actuators</i> , Elsevier Science B.V., Vol. 86, 2000, pp 91-95.
E384	Williams J. et al., "Annealing behaviour of high-dose rare-gas implantations into silicon", from Application of Ion Beams to Materials, 1975, Chap. 1, <i>Inst. Phys. Conf. Ser. No. 28</i> , 1976, pp 30-36.

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E385	Wittmaack et al., "High Fluence Retention of Noble Gases Implanted in Silicon" <i>Radiation Effects</i> , vol. 39, 1978, pp. 81-95.
E386	Wolf, Stanley Ph.D., <i>Silicon Processing for the VLSI Era</i> (vol. 2), Lattice Press, 1990, pp. 66-79.
E387	Wong et al., "Integration of GaN Thin Films With Dissimilar Substrate Materials by Pd-In Metal Bonding and Laser Lift-Off", <i>Journal of Electronic Materials</i> , Vol. 28, No. 12, 1999, pp 1409-1413.
E388	Yamaguchi H. et al., "Intelligent Power IC With Partial Soi Structure", <i>Jpn. J. Appl. Phys.</i> , Vol. 34, 1995, pp 864-868.
E389	Yun et al., "Fractional Implantation Area Effects on Patterned Ion-Cut Silicon Layer Transfer", Dept. of Electrical Eng. and Computer Sciences, University of California, Berkeley, CA, 94720, USA, 1999 IEEE International SOI Conference, Oct, 1999, pp 129-30.
E390	Yun et al., "Thermal and Mechanical Separations of Silicon Layers From Hydrogen Pattern-Implanted Wafers", <i>Journal of Electronic Materials</i> , Vol. 38, No. 8, April 24, 2001, pp 960-964.
E391	Yun, H. et al., "Transfer of Patterned Ion-Cut Silicon Layers", <i>Applied Physics Letters</i> , Vol. 73, No. 19, 1998, pp 2772-2774.
E392	U.S. District Court District of Delaware (Wilmington) Civil Docket For Case #: 1:08-cv-00292-SLR – (54 pgs)
E393	COMPLAINT filed with Jury Demand against MEMC Electronic Materials Inc. - Magistrate Consent Notice to Pltf. ( Filing fee \$ 350, receipt number 152004.) - filed by SOITEC Silicon On Insulator Technologies SA, Commissariat a LEnergie Atomique. (Attachments: # 1 Exhibit 1, # 2 Exhibit 2, # 3 Exhibit 3, # 4 Civil Cover Sheet, # 5 Acknowledgement of Consent Form) (sns, ) (Entered: 05/20/2008) (47 pgs)
E394	Notice of Availability of a U.S. Magistrate Judge to Exercise Jurisdiction (sns, ) (Entered: 05/20/2008) (1 pg)
E395	Report to the Commissioner of Patents and Trademarks for Patent/Trademark Number(s) RE39,484 E; 6,809,009; 7,067,396 B2; (sns, ) (Entered: 05/20/2008) (1 pg)
E396	SUMMONS Returned Executed by SOITEC Silicon On Insulator Technologies SA, Commissariat a LEnergie Atomique. MEMC Electronic Materials Inc. served on 5/19/2008, answer due 6/9/2008. (Kraft, Denise) (Entered: 05/20/2008) (2 pgs)

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E397	MOTION for Pro Hac Vice Appearance of Attorney George W. Neuner, Alan M. Spiro, Brian M. Gaff and Carolyn D'Agincourt - filed by SOITEC Silicon On Insulator Technologies SA, Commissariat a LEnergie Atomique. (Attachments: # 1 Certificate of Compliance Certification by Counsel To Be Admitted Pro Hac Vice, # 2 Certificate of Compliance Certification by Counsel To Be Admitted Pro Hac Vice, # 3 Certificate of Compliance Certification by Counsel To Be Admitted Pro Hac Vice, # 4 Certificate of Compliance Certification by Counsel To Be Admitted Pro Hac Vice, # 5 Certificate of Service)(Kraft, Denise) (Entered: 05/23/2008) (6 pgs).
E398	STIPULATION TO EXTEND TIME Answer to Complaint to 7/9/08 - filed by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 06/05/2008) (1 pg).
E399	MOTION for Pro Hac Vice Appearance of Attorney Robert M. Evans, Jr., David W. Harlan, Richard L. Brophy, Marc W. Vander Tuig - filed by MEMC Electronic Materials Inc.. (Attachments: # 1 Certification of Robert M. Evans, Jr., # 2 Certification of David W. Harlan, # 3 Certification of Richard L. Brophy, # 4 Certification of Marc W. Vander Tuig)(Rogowski, Patricia) (Entered: 06/09/2008) (6 pgs)
E400	MOTION for Pro Hac Vice Appearance of Attorney Michael L. Brody, Richard P. Gilly, Gail J. Standish, Marcus T. Hall and Jason S. Charkow - filed by SOITEC Silicon On Insulator Technologies SA. (Attachments: # 1 Certification By Counsel to be Admitted Pro Hac Vice, # 2 Certification By Counsel to be Admitted Pro Hac Vice, # 3 Certification By Counsel to be Admitted Pro Hac Vice, # 4 Certification By Counsel to be Admitted Pro Hac Vice, # 5 Certification By Counsel to be Admitted Pro Hac Vice)(Kraft, Denise) (Entered: 06/10/2008) (8 pgs)
E401	Disclosure Statement pursuant to Rule 7.1 filed by SOITEC Silicon On Insulator Technologies SA, Commissariat a LEnergie Atomique. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 06/16/2008) (3 pgs)
E402	MOTION to Dismiss Based upon or, in the Alternative, Motion for a More Definite Statement - filed by MEMC Electronic Materials Inc. (Rogowski, Patricia) (Entered: 07/09/2008) (4 pgs)
E403	OPENING BRIEF in Support re 10 MOTION to Dismiss Based upon or, in the Alternative, Motion for a More Definite Statement filed by MEMC Electronic Materials Inc. Answering Brief/Response due date per Local Rules is 7/28/2008. (Rogowski, Patricia) (Entered: 07/09/2008) (15 pgs)
E404	Disclosure Statement pursuant to Rule 7.1 filed by MEMC Electronic Materials Inc. (Rogowski, Patricia) (Entered: 07/09/2008) (3 pgs)

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E405	ANSWERING BRIEF in Opposition re 10 MOTION to Dismiss Based upon or, in the Alternative, Motion for a More Definite Statement filed by Commissariat a L'Energie Atomique. Reply Brief due date per Local Rules is 8/7/2008. (Attachments: # 6 Exhibit A, # 7 Exhibit B, # Certificate of Service) (Kraft, Denise) (Modified on 7/29/2008 (lid). (Entered: 07/28/2008) (29 pgs)
E406	SEALED REPLY BRIEF re 10 MOTION to Dismiss Based upon or, in the Alternative, Motion for a More Definite Statement filed by MEMC Electronic Materials Inc. (Rogowski, Patricia) (Entered: 08/07/2008) REDACTED REPLY BRIEF re 14 - re 10 MOTION to Dismiss Based upon or, in the Alternative, Motion for a More Definite Statement filed by MEMC Electronic Materials Inc. (Attachments: # 1 Exhibit 2, # 2 Exhibit 3, # 3 Exhibit 4, # 4 Exhibit 5, # 5 Unreported Cases, # 6 Certificate of Service) (Rogowski, Patricia) Modified on 8/8/2008 (lid). (Entered: 08/07/2008) (98 pgs)
E407	REDACTED REPLY BRIEF re 14 - re 10 MOTION to Dismiss Based upon or, in the Alternative, Motion for a More Definite Statement filed by MEMC Electronic Materials Inc. (Attachments: # 1 Exhibit 2, # 2 Exhibit 3, # 3 Exhibit 4, # 4 Exhibit 5, # 5 Unreported Cases, # 6 Certificate of Service) (Rogowski, Patricia) Modified on 8/8/2008 (lid). (Entered: 08/07/2008) (98 pgs)
E408	MEMORANDUM ORDER denying 10 MOTION to Dismiss Based upon or, in the Alternative, Motion for a More Definite Statement filed by MEMC Electronic Materials Inc., ORDER, Setting Hearings Telephonic Scheduling Conference set for 3/12/2009 at 9:00 A.M. Signed by Judge Sue L. Robinson on 2/20/2009. (nmf) (Entered: 02/20/2009) (6 pgs)
E409	MOTION for Pro Hac Vice Appearance of Attorney B. Scott Eidson - filed by MEMC Electronic Materials Inc. (Attachments: # 1 Exhibit Certification by Counsel to be Admitted Pro Hac Vice)(Rogowski, Patricia) (Entered: 02/23/2009) (4 pgs)
E410	NOTICE OF SERVICE of Plaintiffs' Initial Disclosures Pursuant to Fed. R. Civ. P. 26(a)(1) by SOITEC Silicon On Insulator Technologies SA, Commissariat a L'Energie Atomique. (Attachments: # 1 Certificate of Service) (Kraft, Denise) (Entered: 02/27/2009) (4 pgs)
E411	ANSWER to 1 Complaint, with Jury Trial Demand, COUNTERCLAIM against all plaintiffs by MEMC Electronic Materials Inc.. (Attachments: # 1 Exhibit A)(Rogowski, Patricia) (Entered: 03/06/2009) (55 pgs)
E412	NOTICE OF SERVICE of MEMC Electronic Materials, Inc.'s Initial Disclosures by MEMC Electronic Materials Inc. (Rogowski, Patricia) (Entered: 03/06/2009) (3 pgs)
E413	PROPOSED ORDER Proposed Scheduling Order re 16 Memorandum and Order, Set Hearings, by SOITEC Silicon On Insulator Technologies SA, Commissariat a L'Energie Atomique. (Kraft, Denise) (Entered: 03/10/2009) (7 pgs)

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E414	Letter to The Honorable Sue L. Robinson from Denise Seastone Kraft, Esq. regarding [Proposed] Scheduling Order - re 21 Proposed Order, 16 Memorandum and Order, Set Hearings,. (Kraft, Denise) (Entered: 03/10/2009) (1 pg)
E415	STIPULATION TO EXTEND TIME to Respond or Otherwise Plead to Defendant's Counterclaim to April 7, 2009 - filed by SOITEC Silicon On Insulator Technologies SA, Commissariat a L'Energie Atomique. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 03/11/2009) (2 pgs)
E416	PROPOSED ORDER Revised Scheduling Order re 21 Proposed Order, 16 Memorandum and Order,, Set Hearings, by SOITEC Silicon On Insulator Technologies SA, Commissariat a L'Energie Atomique. (Kraft, Denise) (Entered: 03/12/2009) (7 pgs)
E417	Letter to The Honorable Sue L. Robinson from Denise Seastone Kraft regarding Revised Scheduling Order Pursuant to 03/12/09 Telephonic Scheduling Conference - re 24 Proposed Order. (Kraft, Denise) (Entered: 03/12/2009) (1 pg)
E418	SCHEDULING ORDER: Case referred to the Magistrate Judge for the purpose of exploring ADR. Joinder of Parties due by 8/14/2009. Amended Pleadings due by 8/14/2009. Discovery due by 4/23/2010. Discovery Conference set for 6/25/2009 04:30 PM in Courtroom 6B before Judge Sue L. Robinson. Dispositive Motions due by 6/25/2010. Answering Brief due 7/16/2010. Reply Brief due 7/30/2010. Oral Argument set for 8/27/2010 09:30 AM in Courtroom 6B before Judge Sue L. Robinson. Claim Construction Opening Briefs due by 6/18/2010. Response Briefs due 7/9/2010. Final Pretrial Conference set for 10/14/2010 04:30 PM in Courtroom 6B before Judge Sue L. Robinson. Jury Trial set for 10/25/2010 09:30 AM in Courtroom 6B before Judge Sue L. Robinson. Signed by Judge Sue L. Robinson on 3/16/2009. (nmf) (Entered: 03/16/2009) (7 pgs)
E419	Order Setting Teleconference: Telephone Conference set for 3/23/2009 at 11:00 AM before Judge Mary Pat Thyngne to discuss ADR. Signed by Judge Mary Pat Thyngne on 3/16/2009. (cak) (Entered: 03/16/2009) (4 pgs)
E420	Order Setting Teleconference: a teleconference has been scheduled for Monday, June 1, 2009 at 10:00 a.m. with Magistrate Judge Thyngne to discuss the status of the case and the parties negotiations. Counsel for MEMC shall initiate the teleconference call to 302-573-6173. IT IS FURTHER ORDERED that the Court is holding September 10, September 14 and September 15, 2009 as possible mediation dates. Counsel are to advise Judge Thyngne by March 30, 2009 if any of these dates works for everyone to schedule the mediation. Signed by Judge Mary Pat Thyngne on 3/23/2009. (cak) (Entered: 03/23/2009) (2 pgs)

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E421	ORDER Setting Mediation Conferences: Mediation Conference TENTATIVELY set for 9/15/2009 at 10:00 AM in Courtroom 2B before Judge Mary Pat Thyng. See order for details. Signed by Judge Mary Pat Thyng on 3/24/2009. (cak) (Entered: 03/24/2009) (6 pgs)
E422	MOTION to Dismiss Based upon Fed. R. Civ. P. 12(b)(1) and (6) and Article III of the United States Constitution - filed by SOITEC Silicon On Insulator Technologies SA, Commissariat a LEnergie Atomique. (Attachments: # 1 Text of Proposed Order, # 2 Certificate of Service)(Kraft, Denise) (Entered: 04/07/2009) (5 pgs)
E423	OPENING BRIEF in Support re 30 MOTION to Dismiss Based upon Fed. R. Civ. P. 12(b)(1) and (6) and Article III of the United States Constitution MOTION to Dismiss Based upon Fed. R. Civ. P. 12(b)(1) and (6) and Article III of the United States Constitution filed by SOITEC Silicon On Insulator Technologies SA, Commissariat a L'Energie Atomique Answering Brief/Response due date per Local Rules is 4/27/2009. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 04/07/2009) (13 pgs)
E424	ANSWER to 19 Answer to Complaint, Counterclaim Partial Answer to Defendant's Counterclaims, Affirmative Defenses and Soitec Counterclaims, COUNTERCLAIM against MEMC Electronic Materials Inc. by SOITEC Silicon On Insulator Technologies SA, Commissariat a LEnergie Atomique. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 04/07/2009) (18 pgs)
E425	NOTICE OF SERVICE of First Request for Production of Documents and Things Directed to Commissariat A L'Energie Atomique; First Request for Production of Documents and Things Directed to SOITEC Silicon on Insulator Technologies, S.A. and Soitec USA, Inc.; and First Set of Interrogatories Directed to SOITEC Silicon on Insulator Technologies, S.A., Soitec USA, Inc. and Commissariat A L'Energie Atomique by MEMC Electronic Materials Inc. (Rogowski, Patricia) (Entered: 04/14/2009) (3 pgs)
E426	STIPULATION TO EXTEND TIME Defendant to File Answering Brief in Opposition to Plaintiffs' Partial Motion to Dismiss Counterclaim Counts II, III, IV, V, and VIII to May 6, 2009 - filed by MEMC Electronic Materials Inc. (Rogowski, Patricia) (Entered: 04/21/2009) (3 pgs)
E427	ANSWER to 32 Answer to Counterclaim,,, of S.O.I. TEC Silicon on Insulator Technologies, S.A. and SOITEC U.S.A., Inc. by MEMC Electronic Materials Inc. (Rogowski, Patricia) (Entered: 04/23/2009) (4 pgs)
E428	STIPULATION TO EXTEND TIME Answering Brief in Opposition to Plaintiffs' Partial Motion to Dismiss Counterclaim Counts II, III, IV, V and VIII to May 15, 2009 - filed by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 05/06/2009) (3 pgs)

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E429	NOTICE OF SERVICE of Soitec's First Set of Interrogatories (Nos. 1-17) and Soitec's First Set of Requests for Production of Documents and Things (Nos. 1-132) by SOITEC Silicon On Insulator Technologies SA, Commissariat a L'Energie Atomique. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 05/06/2009) (2 pgs)
E430	STIPULATION TO EXTEND TIME for Defendant to File an Answering Brief in Opposition to Plaintiffs' Partial Motion to Dismiss Counterclaim Counts II, III, IV, V, and VIII; and STIPULATION TO EXTEND TIME for Plaintiffs to File Responses to MEMC's First Requests For Production of Documents and to MEMC's First Set of Interrogatories to May 29, 2009 - filed by SOITEC Silicon On Insulator Technologies SA, Commissariat a L'Energie Atomique. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 05/13/2009)
E431	NOTICE of Service of (1) Subpoena to Hayes Soloway, P.C., (2) Subpoena to Pearne & Gordon, LLP, (3) Subpoena to Brinks Hofer Gilson & Lione, and (4) Subpoena to Winston & Strawn by MEMC Electronic Materials Inc. (Rogowski, Patricia) (Entered: 05/14/2009) SO ORDERED- re 38 STIPULATION TO EXTEND TIME. Set Briefing Schedule: re 30 MOTION to Dismiss. (Answering Brief due 5/29/2009.) (REFER TO STIPULATION FOR FURTHER DETAILS.). Signed by Judge Sue L. Robinson on 5/15/2009. (lid) (Entered: 05/15/2009)
E432	STIPULATION To Extend Time for Defendant to File Its Answering Brief until June 5, 2009 by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 05/28/2009) SO ORDERED, re 40 Stipulation, Set Briefing Schedule: re 30 MOTION to Dismiss Based upon Fed. R. Civ. P. 12(b)(1) and (6) and Article III of the United States Constitution. (Answering Brief due 6/5/2009.). Signed by Judge Sue L. Robinson on 5/29/2009. (nmf) (Entered: 05/29/2009)
E433	NOTICE OF SERVICE of (1) Soitec's Objections and Responses to MEMC's First Set of Interrogatories; (2) Soitecs Objections and Responses to MEMC's First Request For Production of Documents and Things; (3) CEAs Objections and Responses to MEMC's First Set of Interrogatories; and (4) CEAs Objections and Responses to MEMC's First Request For Production of Documents and Things by SOITEC Silicon On Insulator Technologies SA, Commissariat a L'Energie Atomique. (Attachments: # 1 Certificate of Service) (Kraft, Denise) (Entered: 05/29/2009)
E434	STIPULATION To extend date to June 19, 2009 by which defendant may file an answering brief in opposition to plaintiffs' Partial Motion to Dismiss Counterclaim Counts II, III, IV, V, and VIII by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 06/05/2009)

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E435	NOTICE OF SERVICE of MEMC's Answers to SOITEC's First Set of Interrogatories (Nos. 1-17) and MEMC's Responses to SOITEC's First Set of Requests for Production of Documents and Things (Nos. 1-132) by MEMC Electronic Materials Inc. (Rogowski, Patricia) (Entered: 06/05/2009) SO ORDERED- re <u>42</u> Stipulation to Extend Time. Set Briefing Schedule: re <u>30</u> MOTION to Dismiss. (Answering Brief due 6/19/2009.). Signed by Judge Sue L. Robinson on 6/8/2009. (lid) (Entered: 06/08/2009)
E436	NOTICE OF SERVICE of Soitec's Second Set of Requests For Production of Documents and Things (Nos. 133-135) re <u>41</u> Notice of Service., by SOITEC Silicon On Insulator Technologies SA, Commissariat a L'Energie Atomique. Related document: <u>41</u> Notice of Service., filed by SOITEC Silicon On Insulator Technologies SA, Commissariat a L'Energie Atomique. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 06/11/2009)
E437	Letter to Honorable Sue L. Robinson from Patricia Smink Rogowski regarding Transmitting Form of Protective Order. (Attachments: # <u>1</u> Form of Protective Order, # <u>2</u> Exhibit Exhibit A to Form of Protective Order)(Rogowski, Patricia) (Entered: 06/16/2009)
E438	NOTICE OF SERVICE of MEMC's Second Request for Production of Documents and Things Directed to S.O.I.TEC Silicon on Insulator Technologies, S.A. and Soitec USA, Inc. by MEMC Electronic Materials Inc. (Rogowski, Patricia) (Entered: 06/16/2009) Set/Reset Hearings: Discovery Conference re-set per joint request of counsel for 9/16/2009 08:30 AM in Courtroom 6B before Judge Sue L. Robinson. (nmf) (Entered: 06/18/2009)
E439	STIPULATION TO EXTEND TIME Defendant's Answering Brief in Opposition to Plaintiffs' Partial Motion to Dismiss Counterclaim Counts II, III, IV, V, and VIII to July 2, 2009 - filed by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 06/19/2009) SO ORDERED- re <u>47</u> STIPULATION TO EXTEND TIME. Set Briefing Schedule: re <u>30</u> MOTION to Dismiss (Answering Brief due 7/2/2009.). Signed by Judge Sue L. Robinson on 6/23/2009. (lid) (Entered: 06/23/2009) SO ORDERED, re <u>45</u> Protective Order. Signed by Judge Sue L. Robinson on 6/30/2009. (nmf) (Entered: 06/30/2009)

EXAMINER	DATE CONSIDERED
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FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)		APPLICANT(S): MORICEAU, et al.

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E440	NOTICE of by SOITEC Silicon On Insulator Technologies SA, Commissariat a L'Energie Atomique re <u>30</u> MOTION to Dismiss Based upon Fed. R. Civ. P. 12(b)(1) and (6) and Article III of the United States Constitution MOTION to Dismiss Based upon Fed. R. Civ. P. 12(b)(1) and (6) and Article III of the United States Constitution <i>Notice of Withdrawal of Plaintiffs' Partial Motion to Dismiss Counterclaim Counts II, III, IV, V, and VIII</i> (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2009)
E441	NOTICE OF SERVICE of MEMC's Responses to SOITEC's Second Set of Requests for Production of Documents and Things Directed to MEMC by MEMC Electronic Materials Inc. (Rogowski, Patricia) (Entered: 07/14/2009)
E442	STIPULATION and [Proposed] Order to File an Amended Complaint by SOITEC Silicon On Insulator Technologies SA, Commissariat a L'Energie Atomique. (Attachments: # <u>1</u> Exhibit A, # <u>2</u> Certificate of Service)(Kraft, Denise) (Entered: 07/16/2009)
E443	NOTICE OF SERVICE of Soitec's Objections and Responses to MEMC's Second Request For Production of Documents and Things Directed To Soitec re <u>46</u> Notice of Service by SOITEC Silicon On Insulator Technologies SA, Commissariat a L'Energie Atomique. Related document: <u>46</u> Notice of Service filed by MEMC Electronic Materials Inc. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/16/2009)
E444	NOTICE of Withdrawal of Docket Entry 51 by SOITEC Silicon On Insulator Technologies SA, Commissariat a L'Energie Atomique re <u>51</u> Notice of Service, (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/17/2009)
E445	NOTICE OF SERVICE of SOITEC's Objections and Responses to MEMC's Second Request for Production of Documents and Things Directed to SOITEC re <u>46</u> Notice of Service by SOITEC Silicon On Insulator Technologies SA, Commissariat a L'Energie Atomique. Related document: <u>46</u> Notice of Service filed by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/17/2009)
E446	NOTICE OF SERVICE of MEMC Electronic Materials, Inc.'s Second Set of Interrogatories Directed to S.O.I.TEC Silicon on Insulator Technologies, S.A., SOITEC USA, Inc. and Commissariat A L'Energie Atomique by MEMC Electronic Materials Inc. (Rogowski, Patricia) (Entered: 07/17/2009)
E447	NOTICE OF SERVICE of Soitec's Production of Documents Bates Numbered SCEA 00000001 to SCEA 00002442 by SOITEC Silicon On Insulator Technologies SA, Commissariat a L'Energie Atomique. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/17/2009) SO ORDERED, re <u>50</u> Stipulation. Signed by Judge Sue L. Robinson on 7/20/2009. (nmf) (Entered: 07/20/2009)

EXAMINER	DATE CONSIDERED
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FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)		APPLICANT(S): MORICEAU, et al.

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E448	NOTICE OF SERVICE of MEMC's Production of Documents Bates Numbered MEMC0300000 to MEMC0306530 by MEMC Electronic Materials Inc. (Rogowski, Patricia) (Entered: 07/20/2009)
E449	First AMENDED COMPLAINT for Patent Infringement against MEMC Electronic Materials Inc. - filed by SOITEC Silicon On Insulator Technologies SA, Commissariat a L'Energie Atomique. (Attachments: # <u>1</u> Exhibit Exhibit 1, # <u>2</u> Exhibit Exhibit 2, # <u>3</u> Exhibit Exhibit 3, # <u>4</u> Exhibit Exhibit 4, # <u>5</u> Certificate of Service)(Kraft, Denise) (Entered: 07/21/2009)
E450	NOTICE OF SERVICE of Soitec S.A.'s Second Set of Interrogatories (Nos. 18-22) and CEA's First Set of Interrogatories (Nos. 1-11) by SOITEC Silicon On Insulator Technologies SA, Commissariat a L'Energie Atomique. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/23/2009)
E451	NOTICE OF SERVICE of S.O.I.TEC SILICON ON INSULATOR TECHNOLOGIES, S.A. and COMMISSARIAT A L'ENERGIE ATOMIQUE SUPPLEMENTAL PRODUCTION OF DOCUMENTS BATES NUMBERED SLIT 00000001 to SLIT 00049728 re <u>43</u> Notice of Service, by SOITEC Silicon On Insulator Technologies SA, Commissariat a L'Energie Atomique. Related document: <u>43</u> Notice of Service, filed by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/27/2009)
E452	ANSWER to Amended Complaint ANSWER to <u>57</u> Amended Complaint, with Under Federal Rule of Civil Procedure 38, MEMC demands a trial by jury on all issues so triable., COUNTERCLAIM against all plaintiffs by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Exhibit A, # <u>2</u> Certificate of Service)(Rogowski, Patricia) (Entered: 08/03/2009)
E453	NOTICE OF SERVICE of MEMC's Production of Documents Bates Numbered MEMC0300000 - MEMC0337055 by MEMC Electronic Materials Inc. (Rogowski, Patricia) (Entered: 08/05/2009)
E454	NOTICE OF SERVICE of S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's Revised Supplemental Production of Documents Bates Numbered SLIT00000001 - SLIT0004886; SLIT00004931 SLIT00004985; SLIT00005169 SLIT00005174; SLIT00005241 SLIT00006368; and SLIT00006886 - SLIT00049728 re <u>59</u> Notice of Service, by SOITEC U.S.A., Inc., SOITEC Silicon On Insulator Technologies SA, Commissariat a L'Energie Atomique. Related document: <u>59</u> Notice of Service, filed by SOITEC Silicon On Insulator Technologies SA, Commissariat a L'Energie Atomique. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 08/06/2009)

EXAMINER	DATE CONSIDERED
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FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
<b>LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT</b>	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)		APPLICANT(S): MORICEAU, et al.

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E455	STIPULATION TO EXTEND TIME to Answer or Otherwise Respond to MEMC's Amended Counterclaims to August 31, 2009 - filed by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc., Commissariat a L'Energie Atomique. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 08/25/2009)
E456	NOTICE OF SERVICE of S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's Supplemental Production of Documents Bates Numbered SOIT 00000001 to SOIT 00003528 and SLIT 00049729 to SLIT 00060612 by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc., Commissariat a L'Energie Atomique. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 08/25/2009)
E457	NOTICE OF SERVICE of MEMC's Production of Documents Bates Numbered MEMC0337056 to MEMC0337503 and MEMC0337504-MEMC0338047 by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 08/26/2009)
E458	NOTICE OF SERVICE of (1) SOITECs Supplemental Responses to MEMC Electronic Materials, Inc's First Set of Interrogatories; and (2) CEAs Supplemental Responses to MEMC Electronic Materials, Inc.s First Set of Interrogatories re 41 Notice of Service,, by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc., Commissariat a L'Energie Atomique. Related document: 41 Notice of Service,, filed by SOITEC Silicon On Insulator Technologies SA, Commissariat a L'Energie Atomique. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 08/26/2009)
E459	NOTICE OF SERVICE of MEMC's Supplemental Answers to SOITEC's First Set of Interrogatories by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 08/27/2009) SO ORDERED- re 63 STIPULATION TO EXTEND TIME. Set/Reset Answer Deadlines: SOITEC Silicon On Insulator Technologies SA answer due 8/31/2009; Commissariat a L'Energie Atomique answer due 8/31/2009; SOITEC U.S.A., Inc. answer due 8/31/2009. Signed by Judge Sue L. Robinson on 8/27/2009. (lid) (Entered: 08/27/2009)
E460	ANSWER to 60 Answer to Amended Complaint, Counterclaim,, COUNTERCLAIM Reply to Defendant's Amended Counterclaims, Counterclaims And Affirmative Defenses against MEMC Electronic Materials Inc. by SOITEC Silicon On Insulator Technologies SA, Commissariat a L'Energie Atomique, SOITEC U.S.A., Inc. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 08/31/2009)
E461	NOTICE OF SERVICE of MEMC's THIRD SET OF INTERROGATORIES DIRECTED TO S.O.I.TEC SILICON ON INSULATOR TECHNOLOGIES, S.A., SOITEC USA, INC., AND COMMISSARIAT A L'ENERGIE ATOMIQUE by MEMC Electronic Materials Inc. (Rogowski, Patricia) (Entered: 09/01/2009)

EXAMINER	DATE CONSIDERED
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FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
<b>LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT</b>	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)	APPLICANT(S): MORICEAU, et al.	

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E462	ANSWER to 68 Answer to Counterclaim,,, by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 09/14/2009). Minute Entry for proceedings held before Judge Sue L. Robinson - Discovery Conference held on 9/16/2009. (Court Reporter V. Gunning.) (nmf) (Entered: 09/16/2009)
E463	NOTICE OF SERVICE of Soitec S.A.'s Third Set of Interrogatories (Nos. 23-27) re <u>58</u> Notice of Service, by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc., Commissariat a LEnergie Atomique. Related document: <u>58</u> Notice of Service, filed by SOITEC Silicon On Insulator Technologies SA, Commissariat a LEnergie Atomique. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 09/22/2009)
E464	NOTICE OF SERVICE of MEMC ELECTRONIC MATERIALS INC.'S ANSWERS TO SOITEC S.A.'S SECOND SET OF INTERROGATORIES (NOS. 8-22) and MEMC ELECTRONIC MATERIALS, INC.'S ANSWERS TO CEA'S FIRST SET OF INTERROGATORIES (NOS. 1-11) by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 10/16/2009)
E465	NOTICE OF SERVICE of S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's Supplemental Production of Documents Bates Numbered SOIT 00003529 to SOIT 00004244 by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc., Commissariat a LEnergie Atomique. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 10/16/2009)
E466	NOTICE OF SERVICE of S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's Supplemental Production of Documents Bates Numbered SOIT 00003258.001-.057; SOIT 00003342.001-.007; SOIT 00003343.001-.009; (Con't) - SOIT 00003409.001-.015; and SOIT 00003469.001-.015 by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc., Commissariat a LEnergie Atomique. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 10/16/2009)
E467	NOTICE OF SERVICE of SOITEC/CEA Parties' Objections and Responses to MEMC Electronic Materials, Inc.'s Second Set of Interrogatories by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc., Commissariat a LEnergie Atomique. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 10/16/2009)
E468	NOTICE OF SERVICE of S.O.I.TEC Silicon On Insulator Technologies, S.A. and Commissariat LEnergie Atomique Supplemental Production of Documents Bates Numbered SOIT 00004245 to SOIT 00205027 by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc., Commissariat a LEnergie Atomique. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Additional attachment(s) added on 10/23/2009; # <u>2</u> revised) (lid). Modified on 10/23/2009 (lid). (Entered: 10/16/2009)
EXAMINER	DATE CONSIDERED

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FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)	APPLICANT(S): MORICEAU, et al.	

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E469	MOTION to Bifurcate <i>the Issues of Willfulness and Damages for Purposes of Discovery and Trial and proposed Form of Order</i> - filed by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 10/20/2009). CORRECTING ENTRY: Docket clerk deleted D.I. 78 (opening brief) due to document being filed improperly. Counsel is advised to re-file document using the OPENING BRIEF event code rather than the combined opening and answering brief event code. (lid) (Entered: 10/21/2009)
E470	OPENING BRIEF in Support re <u>77</u> MOTION to Bifurcate <i>the Issues of Willfulness and Damages for Purposes of Discovery and Trial and proposed Form of Order</i> filed by MEMC Electronic Materials Inc.. Answering Brief/Response due date per Local Rules is 11/9/2009. (Attachments: # <u>1</u> Exhibit A, # <u>2</u> Exhibit B, # <u>3</u> Exhibit C)(Rogowski, Patricia) (Entered: 10/21/2009)
E471	NOTICE OF SERVICE of MEMC's PRODUCTION OF DOCUMENTS BATES NUMBERED MEMC0338048-MEMC0345027 by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 10/23/2009)
E472	NOTICE OF SERVICE of S.O.I.TEC Silicon On Insulator Technologies, S.A. and Commissariat a L'Energie Atomique Supplemental Production of Replacement Documents Bates Numbered SCEA 00001337 TO SCEA 00001339; SCEA 00002434 TO SCEA 00002439; SOIT 00007961; SOIT 00006718 TO SOIT 00006727; and SOIT 00007595 TO SOIT 00007598 by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc., Commissariat a L'Energie Atomique. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 10/23/2009) CORRECTING ENTRY: Pursuant to request of counsel, correct pdf of D.I. 76 has been attached and text of entry has been modified to correct bates number (lid) (Entered: 10/23/2009)
E473	NOTICE OF SERVICE of S.O.I.TEC Silicon On Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's Supplemental Production Of Documents Bates Numbered SOIT 00205028 to SOIT 00206175; SCEA 00002443 to SCEA 00003974; and SLIT 00060613 to SLIT 00063784 by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc., Commissariat a L'Energie Atomique. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 10/28/2009)
E474	NOTICE OF SERVICE of MEMC'S ANSWERS TOSOITEC S.A.'S THIRD SET OF INTERROGATORIES (NOS. 23-27) by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 10/28/2009)

EXAMINER	DATE CONSIDERED
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FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
<b>LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT</b>	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)		APPLICANT(S): MORICEAU, et al.

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E475	NOTICE OF SERVICE OF S.O.I.TEC Silicon On Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's Supplemental Production Of Documents Bates Numbered SOIT 00206176 to SOIT 00206183 by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc., Commissariat a L'Energie Atomique. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 10/28/2009)
E476	NOTICE OF SERVICE OF SOITEC/CEA Parties' Objections and Responses to MEMC Electronic Materials, Inc.'s Third Set of Interrogatories by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc., Commissariat a L'Energie Atomique. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 10/29/2009)
E477	Cross MOTION to Bifurcate <i>all Collateral Issues</i> - filed by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc., Commissariat a L'Energie Atomique. (Attachments: # 1 Text of Proposed Order, # 2 Certificate of Service)(Kraft, Denise) (Entered: 11/09/2009)
E478	ANSWERING BRIEF in Opposition re <u>85</u> Cross MOTION to Bifurcate <i>all Collateral Issues</i> , <u>77</u> MOTION to Bifurcate <i>the Issues of Willfulness and Damages for Purposes of Discovery and Trial and proposed Form of Order</i> filed by SOITEC Silicon On Insulator Technologies SA, Commissariat a L'Energie Atomique. Reply Brief due date per Local Rules is 11/20/2009. (Attachments: # 1 Exhibit, # 2 Exhibit, # 3 Exhibit, # 4 Exhibit, # 5 Exhibit, # 6 Exhibit, # 7 Exhibit, # 8 Exhibit, # 9 Exhibit, # 10 Exhibit, # 11 Exhibit, # 12 Declaration, # 13 Certificate of Service)(Kraft, Denise) (Entered: 11/09/2009)
E479	NOTICE OF SERVICE of CEA's Second Set of Interrogatories (Nos. 12-16) by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc., Commissariat a L'Energie Atomique. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 11/11/2009)  CORRECTING ENTRY: Pursuant to request of counsel, Exhibit A to D.I. 86 has been deleted and will be re-filed under seal by counsel at a later time (lid) (Entered: 11/12/2009)
E480	SEALED EXHIBIT re <u>86</u> Answering Brief in Opposition,, by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc., Commissariat a L'Energie Atomique. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 11/12/2009)
E481	REPLY BRIEF re <u>77</u> MOTION to Bifurcate <i>the Issues of Willfulness and Damages for Purposes of Discovery and Trial and proposed Form of Order</i> filed by MEMC Electronic Materials Inc.. (Attachments: # 1 Exhibit 1, # 2 Exhibit 2, # 3 Exhibit 3)(Rogowski, Patricia) (Entered: 11/17/2009)
E482	ANSWERING BRIEF in Opposition re <u>85</u> Cross MOTION to Bifurcate <i>all Collateral Issues</i> filed by MEMC Electronic Materials Inc.. Reply Brief due date per Local Rules is 12/3/2009. (Rogowski, Patricia) (Entered: 11/19/2009)
EXAMINER	DATE CONSIDERED

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FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)	APPLICANT(S): MORICEAU, et al.	

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E483	NOTICE OF SERVICE of S.O.I.TEC Silicon On Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's Supplemental Production of Documents Bates Numbered SOIT 00206184 to SOIT 00206997 by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 11/23/2009)
E484	NOTICE OF SERVICE of (1) Subpoena in a Civil Case to J. William Dockrey; (2) Subpoena in a Civil Case to Allan Fanucci, Esq.; (3) Amended Notice of Videotaped Deposition of Saeed Pirooz; (4) Notice of Videotaped Deposition of Commissariat a L'Energie Atomique; and (5) Notice of Videotaped Deposition of S.O.I.TEC Silicon on Insulator Technologies, S.A. and Soitec U.S.A., Inc. by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 11/30/2009)
E485	NOTICE OF SERVICE of S.O.I.TEC Silicon On Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's Supplemental Production of Documents Bates Numbered BHRO00000001 to BHRO00036157 by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 12/02/2009)
E486	REPLY BRIEF re 85 Cross MOTION to Bifurcate <i>all Collateral Issues</i> filed by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # 1 Exhibit Declaration of Marcus T. Hall in Support of Plaintiffs' Reply Re: Cross-Motion to Bifurcate all Collateral Issues)(Kraft, Denise) (Entered: 12/03/2009)
E487	NOTICE OF SERVICE of S.O.I.TEC Silicon On Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's Production of Three Boxes of Wafer Samples by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 12/08/2009). Set Hearings: Discovery Conference set for 12/21/2009 04:00 PM in Courtroom 6B before Judge Sue L. Robinson. (nmf) (Entered: 12/09/2009).
E488	NOTICE OF SERVICE of (1) SIX CARTONS OF 300 MM WAFER SAMPLES AND 1 CARTON OF 200 MM WAFER SAMPLES; (2) DOCUMENTS MARKED MEMC0345028-MEMC0345084; (3) DOCUMENTS MARKED MEMC0345085-MEMC0345133; (4) MEMC'S ANSWERS TO CEA'S SECOND SET OF INTERROGATORIES (NOS. 12-16); AND (5) MEMC'S FIRST SET OF REQUESTS FOR ADMISSION TO S.O.I.TEC SILICON ON INSULATOR TECHNOLOGIES, S.A. AND SOITEC USA, INC. by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 12/14/2009)
E489	MOTION for Leave to File <i>Stipulated Motion for Leave to File a Sur-Reply Brief in Support of MEMC's Motion to Bifurcate</i> - filed by MEMC Electronic Materials Inc.. (Attachments: # 1 Exhibit 1)(Rogowski, Patricia) (Entered: 12/14/2009)
EXAMINER	DATE CONSIDERED

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)	APPLICANT(S): MORICEAU, et al.	

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E490	REDACTED VERSION of 88 Exhibit to a Document <i>Cross Motion to Bifurcate all Collateral Issues</i> by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (Entered: 12/14/2009). SO ORDERED- re 97 MOTION for Leave to File. Signed by Judge Sue L. Robinson on 12/16/2009. (lid) (Entered: 12/16/2009)
E491	SUR-REPLY BRIEF re 77 MOTION to Bifurcate <i>the Issues of Willfulness and Damages for Purposes of Discovery and Trial and proposed Form of Order MEMC's SUR-REPLY BRIEF IN SUPPORT OF ITS MOTION TO BIFURCATE THE ISSUES OF WILLFULNESS AND DAMAGES FOR PURPOSES OF DISCOVERY AND TRIAL</i> filed by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 12/16/2009)
E492	NOTICE OF SERVICE OF S.O.I.TEC Silicon On Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's Supplemental Production of Documents Bates Numbered SOIT 00207008 TO SOIT 00207591 by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 12/17/2009). Minute Entry for proceedings held before Judge Sue L. Robinson - Conference held on 12/21/2009. (Court Reporter V. Gunning.) (nmf) (Entered: 12/22/2009). ORAL ORDER by Judge Sue L. Robinson in open court on 12/21/2009 granting 77 MOTION to Bifurcate <i>the Issues of Willfulness and Damages for Purposes of Discovery and Trial and proposed Form of Order</i> , denying 85 Cross MOTION to Bifurcate <i>all Collateral Issues</i> . (nmf) (Entered: 12/22/2009).
E493	NOTICE OF SERVICE OF S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat L'Energie Atomique's Production 12 of CD-ROM Documents Bates Numbered SOIT 00207008 TO SOIT 00207591 by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc..(Kraft, Denise) (Entered: 12/22/2009)
E494	NOTICE OF SERVICE OF S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat L'Energie Atomique's Supplemental Production of Documents Bates Numbered BHRO00036158 to BHRO00036584, served on December 11, 2009; and S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat L'Energie Atomique's Supplemental Production of Documents Bates Numbered BHRO00036585 to BHRO00036731, served on December 18, 2009 by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 12/22/2009). CORRECTING ENTRY: Pursuant to conversation docket clerk deleted Notice of filing due to document being filed improperly. Counsel will re-file document at a later time. (lid) (Entered: 01/04/2010).

EXAMINER	DATE CONSIDERED
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FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)	APPLICANT(S): MORICEAU, et al.	

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E495	NOTICE OF SERVICE of S.O.I.TEC Silicon on Insulator Technologies, S.A. and Soitec USA, Inc.'s Objections and Responses to MEMC's November 25, 2009 Notice of 30(b)(6) Deposition of Soitec, and Commissariat a l'Energie Atomique's Objections and Responses to MEMC's November 25, 2009 Notice of 30(b)(6) Deposition of CEA by Commissariat a l'Energie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 01/04/2010).
E496	STIPULATION To Amend Scheduling Order re 26 Scheduling Order,,, by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 01/06/2010)
E497	NOTICE OF SERVICE of S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat L'Energie Atomique's Production of Documents Bates Numbered HS0000001 to HS0000792 by Commissariat a l'Energie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 01/06/2010)
E498	NOTICE OF SERVICE of Documents Marked (1) MEMC0345134-MEMC0391283 and (2) MEMC0391284-MEMC0413109 by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 01/07/2010). SO ORDERED- re 104 Stipulation Amending Scheduling Order. ORDER- Setting Scheduling Order Deadlines ( Claims Construction Opening Brief due by 6/18/2010., Discovery due by 6/18/2010.)(REFER TO STIPULATION FOR FURTHER DETAILS). Signed by Judge Sue L. Robinson on 1/7/2010. (lid) (Entered: 01/07/2010).
E499	NOTICE OF SERVICE of S.O.I.TEC Silicon on Insulator Technologies, S.A. and Soitec USA, Inc.'s Responses to MEMC Electronic Materials, Inc.'s First Set of Requests for Admission by Commissariat a l'Energie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 01/11/2010)
E500	NOTICE OF SERVICE of Documents Marked MEMC0413110-MEMC0459972 by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 01/13/2010)
E501	NOTICE OF SERVICE of Notice of Videotaped Depositions of Emmanuel Huyghe, Clotilde Turleque, Christophe Maleville and Hubert Moriceau by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 01/14/2010)
E502	NOTICE OF SERVICE of Notice of Videotaped Deposition of Norman Soloway by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 01/14/2010)
E503	NOTICE OF SERVICE of Notice of Videotaped Depositions of (1) Emmanuel Arene, (2) Bruno Ghyselen, (3) Thierry Barge, (4) Chrystelle Legahe, (5) Konstantine Bourdelle, (6) Andre-Jacques Auberton-Herve, (7) Bernard Aspar, (8) Thierry Poumeyrol, and (9) Michel Bruel by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 01/20/2010)
EXAMINER	DATE CONSIDERED

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
<b>LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT</b>	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)		APPLICANT(S): MORICEAU, et al.

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E504	NOTICE OF SERVICE of S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat L'Energie Atomique's Production 16 of CD-ROM Documents Bates Numbered SOIT 00207592 to SOIT 00218102 by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 01/20/2010)
E505	MOTION for Pro Hac Vice Appearance of Attorney Laura K. Carter - filed by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # 1 Text of Proposed Order, # 2 Certification, # 3 Certificate of Service)(Kraft, Denise) (Entered: 01/21/2010). SO ORDERED- re 113 MOTION for Pro Hac Vice Appearance of Attorney Laura K. Carter. Signed by Judge Sue L. Robinson on 1/26/2010. (lid) (Entered: 01/26/2010)
E506	NOTICE OF SERVICE of S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat L'Energie Atomique's Production 17 of CD-Rom Documents Bates Numbered SOIT 00218103 to SOIT 00219113 by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 01/27/2010)
E507	NOTICE OF SERVICE of S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat L'Energie Atomique's Production of Documents Bates Numbered SOIT 00219114 to SOIT 00219229 by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 01/27/2010)
E508	NOTICE OF SERVICE of Documents Marked (1) MEMC0459973-MEMC-0526213; (2) MEMC0526214-MEMC-0526273; and (3) MEMC0484547-MEMC0526213 by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 01/29/2010)
E509	NOTICE OF SERVICE of Six DVDs Containing Documents Marked MEMC0526274-MEMC0582949 by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 02/02/2010)
E510	NOTICE OF SERVICE of Documents Marked MEMC0582950 - MEMC0618792 by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 02/08/2010)
E511	NOTICE OF SERVICE of Documents Marked (1) MEMC0618793-MEMC0697890 and (2) MEMC0697891-MEMC0715676 by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 02/12/2010)
E512	NOTICE OF SERVICE of Documents Marked MEMC0715677-MEMC0772697 by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 02/18/2010)
E513	NOTICE OF SERVICE of Notice of Videotaped Deposition by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 02/19/2010)

EXAMINER	DATE CONSIDERED
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FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
<b>LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT</b>	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)		APPLICANT(S): MORICEAU, et al.

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E514	NOTICE OF SERVICE of S.O.I.TEC SILICON ON INSULATOR TECHNOLOGIES, S.A. and COMMISSARIAT LNERGIE ATOMIQUES PRODUCTION 19 OF CD-ROM DOCUMENTS BATES NUMBERED SOIT 00219230 - SOIT 00242462, SOIT 00242514 - SOIT 00271070, SOIT 00271093 - SOIT 00277765, SOIT 00277802 - SOIT 00280854 by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 03/02/2010)
E515	NOTICE OF SERVICE of S.O.I.TEC SILICON ON INSULATOR TECHNOLOGIES, S.A. and COMMISSARIAT LNERGIE ATOMIQUES PRODUCTION 20 OF CD-ROM DOCUMENTS BATES NUMBERED SOIT 00280855 - SOIT 00310785 by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 03/02/2010)
E516	NOTICE OF SERVICE of S.O.I.TEC SILICON ON INSULATOR TECHNOLOGIES, S.A. and COMMISSARIAT LNERGIE ATOMIQUES PRODUCTION 21 OF CD-ROM DOCUMENTS BATES NUMBERED SCEA 00003975 - SCEA 00004146 and SOIT 00310786 - SOIT 00336534 by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 03/02/2010)
E517	NOTICE OF SERVICE of S.O.I.TEC SILICON ON INSULATOR TECHNOLOGIES, S.A. and COMMISSARIAT LNERGIE ATOMIQUES PRODUCTION 22 OF CD-ROM DOCUMENTS BATES NUMBERED SCEA 00004147 - SCEA 00031465 and SOIT 00336535 - SOIT 00355547 and SOIT 00355554 - SOIT 00359693 by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 03/02/2010)
E518	NOTICE OF SERVICE of S.O.I.TEC Silicon On Insulator Technologies, S.A.'s Fourth Set of Interrogatories (Nos. 28-29) Directed to MEMC Electronic Materials, Inc. by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Additional attachment(s) added on 3/24/2010: # 1 Certificate of Service) (fms). (Entered: 03/03/2010)
E519	STIPULATION to Amend Scheduling Order re 26 Scheduling Order,, by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 03/12/2010). SO ORDERED- re 127 Stipulation to Amend Scheduling Order. ORDER- Setting Scheduling Order Deadlines ( Claims Construction Opening Brief due by 6/18/2010., Discovery due by 6/18/2010.) (REFER TO STIPULATION FOR DETAILS). Signed by Judge Sue L. Robinson on 3/15/2010. (lid) (Entered: 03/15/2010)

EXAMINER	DATE CONSIDERED
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FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
<b>LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT</b>	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)		APPLICANT(S): MORICEAU, et al.

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E520	NOTICE OF SERVICE of (1) MEMC Electronic Materials, Inc.'s Second Set of Requests for Admission Directed to Plaintiffs and (2) MEMC Electronic Materials, Inc.'s Fourth Set of Interrogatories Directed to S.O.I.TEC Silicon On Insulator Technologies, S.A., SOITEC USA, Inc. and Commissariat A L'Energie Atomique by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 03/23/2010). CORRECTING ENTRY: Per request of counsel, the pdf attached to D.I. 126 (NOTICE OF SERVICE of S.O.I.TEC Silicon On Insulator Technologies, S.A.'s Fourth Set of Interrogatories (Nos. 28-29) Directed to MEMC Electronic Materials, Inc. by Commissariat A L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.) has been deleted and replaced with the proper attachment with the correct date. (fms) (Entered: 03/24/2010). CORRECTING ENTRY: Per request of counsel, D.I. 129 has been deleted and will be re-filed at a later time. (lid) (Entered: 03/29/2010)
E521	NOTICE OF SERVICE of S.O.I.TEC Silicon On Insulator Technologies, S.A.'s Production 23 Bates Numbered SOIT 00359694 and SOIT 00359695, including Wafer Samples by SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 03/29/2010)
E522	NOTICE OF SERVICE of S.O.I.TEC Silicon On Insulator Technologies, S.A.'s Production 24 of CD-ROM Documents Bates Numbered SOIT 00359696 - SOIT 00419315 by SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 04/01/2010)
E523	NOTICE OF SERVICE of Electronic Production of OCR Text Files related to: (1) S.O.I.TEC Silicon On Insulator Technologies, S.A.'s Production 19 Bates Numbered SOIT 00219230 - SOIT 00242462; SOIT 00242514 - SOIT 00271070; SOIT 00271093 - SOIT 00277765; SOIT 00277802 - SOIT 00280854; (2) S.O.I.TEC Silicon on Insulator Technologies, S.A.'s Production 20 Bates Numbered SOIT 00280855 - SOIT 00310785; and (3) S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat A L'Energie Atomique's Production 22 Bates Numbered SCEA 00004147 - SCEA 00031465; SOIT 00336535 - SOIT 00355547, and SOIT 00355554 - SOIT 00359693 by Commissariat A L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 04/07/2010)
E524	NOTICE OF SERVICE of (1) Documents marked MEMC0772698-MEMC0775891; (2) Documents marked CRAV00000001-CRAV000000098; and (3) Document marked MEMC0775892 by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 04/07/2010)

EXAMINER	DATE CONSIDERED
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FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
<b>LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT</b>	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)	APPLICANT(S): MORICEAU, et al.	

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E525	NOTICE OF SERVICE of MEMC ELECTRONIC MATERIALS, INC.'S SUPPLEMENTAL ANSWER TO CEA'S FIRST SET OF INTERROGATORIES, MEMC'S ANSWERS TO SOITEC S.A.'S FOURTH SET OF INTERROGATORIES (NOS. 28-29), and MEMC'S SUPPLEMENTAL ANSWERS TO SOITEC S.A.'S THIRD SET OF INTERROGATORIES (NO. 23) by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 04/07/2010). Set Hearings: Discovery Conference set for 4/23/2010 09:30 AM in Courtroom 6B before Judge Sue L. Robinson. (nmf) (Entered: 04/21/2010)
E526	NOTICE OF SERVICE of S.O.I.TEC Silicon On Insulator Technologies, S.A.'s Production of Documents Bates Numbered SOIT 00419316 (updated from previously produced documents Bates numbered SOIT 00000159 - SOIT 00000161) by SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 04/22/2010). Minute Entry for proceedings held before Judge Sue L. Robinson - Discovery Conference held on 4/23/2010. (Court Reporter V. Gunning.) (nmf) (Entered: 04/23/2010)
E527	NOTICE OF SERVICE of S.O.I.TEC Silicon On Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's electronic production of: (1) Production #25 Bates Numbered SCEA00031466-SCEA00032999; SOIT00419316-SOIT00422470; and SOIT00422478-SOIT00461551; (2) Production #26 Bates Numbered SCEA00033000-SCEA00165680; SCEA00165686-SCEA00167229; SCEA00167232-SCEA00167288; and SOIT00461552-SOIT00474611; and (3) Production #27 Bates Numbered SCEA00167289-SCEA00167291; and SOIT00474611-SOIT00476375 by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 04/29/2010)
E528	NOTICE OF SERVICE of Commissariat a L'Energie Atomique's Production #28 of CD-ROM Documents Bates Numbered SCEA00167292-SCEA00167308 by Commissariat a L'Energie Atomique. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 04/29/2010)
E529	NOTICE OF SERVICE of (1) Notice of Videotaped Deposition (Michael Bruel) and (2) Notice of Videotaped Deposition (S.O.I.TEC Silicon on Insulator Technologies, S.A. and SOITEC USA, Inc.) by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 05/03/2010)
E530	NOTICE OF SERVICE of (1) DVD Containing Video Marked CRA V00000099; (2) CD Containing Documents Marked MEMC0775893-MEMC0775948; (3) CD Containing Documents Marked MEMC0775949-MEMC0775954; and (4) DVD Containing Documents Marked MEMC0775955-MEMC0781961 by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 05/03/2010)
EXAMINER	DATE CONSIDERED

EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)		APPLICANT(S): MORICEAU, et al.

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E531	NOTICE OF SERVICE of Commissariat a L'Energie Atomique's Production #29 of CD-ROM Documents Bates Numbered SCEA 00167309 - SCEA 00167315 by Commissariat a L'Energie Atomique. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 05/03/2010)
E532	NOTICE OF SERVICE of (1) S.O.I.TEC Silicon On Insulator Technologies, S.A., SOITEC USA, Inc., and Commissariat a L'Energie Atomique's Responses To MEMC's Fourth Set of Interrogatories; and (2) S.O.I.TEC Silicon On Insulator Technologies, S.A., and Commissariat a L'Energie Atomique's Responses To MEMC's Second Set of Requests for Admissions re <u>128</u> Notice of Service, by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. Related document: <u>128</u> Notice of Service, filed by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 05/04/2010). Reset Hearings: Oral Argument re-set per joint request of counsel for 9/3/2010 09:30 AM in Courtroom 6B before Judge Sue L. Robinson. (nmf) (Entered: 05/05/2010)
E533	MOTION for Discovery MOTION FOR THE ADMISSION OF THE EXPERT TESTIMONY OF JOHN T. GOOLKASIAN RELATING TO THE CERTIFICATE OF CORRECTION FOR U.S. PATENT NO. 7,067,396 - filed by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 05/07/2010)
E534	OPENING BRIEF in Support re <u>141</u> MOTION for Discovery <i>MOTION FOR THE ADMISSION OF THE EXPERT TESTIMONY OF JOHN T. GOOLKASIAN RELATING TO THE CERTIFICATE OF CORRECTION FOR U.S. PATENT NO. 7,067,396</i> filed by MEMC Electronic Materials Inc.. Answering Brief/Response due date per Local Rules is 5/24/2010. (Attachments: # <u>1</u> Exhibit 1, # <u>2</u> Exhibit 2, # <u>3</u> Exhibit 3, # <u>4</u> Exhibit 4, # <u>5</u> Exhibit 5, # <u>6</u> Exhibit 6, # <u>7</u> Exhibit 7, # <u>8</u> Exhibit 8, # <u>9</u> Exhibit 9, # <u>10</u> Exhibit 10, # <u>11</u> Exhibit 11, # <u>12</u> Exhibit 12, # <u>13</u> Exhibit 13, # <u>14</u> Exhibit 14, # <u>15</u> Exhibit 15)(Rogowski, Patricia) (Entered: 05/07/2010)
E535	NOTICE OF SERVICE of CD-ROM including re-submittal of documents Bates numbered SOIT 00310798-00336526 as Document Bates numbered SOIT 00310798 in native format by SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 05/20/2010)
E536	NOTICE OF SERVICE of Amended Notices of Videotaped Deposition of (1) Dr. Bernard Aspar and (2) Dr. Michel Bruel by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 05/21/2010)

EXAMINER	DATE CONSIDERED
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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609, Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)		APPLICANT(S): MORICEAU, et al.

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E537	ANSWERING BRIEF in Opposition re <u>141</u> MOTION for Discovery <i>MOTION FOR THE ADMISSION OF THE EXPERT TESTIMONY OF JOHN T. GOOLKASIAN RELATING TO THE CERTIFICATE OF CORRECTION FOR U.S. PATENT NO. 7,067,396 Plaintiff's Answering Brief in Opposition to Defendant's Motion For the Admission of Expert Testimony of John T. Goolkasian</i> filed by SOITEC Silicon On Insulator Technologies SA. Reply Brief due date per Local Rules is 6/4/2010. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 05/24/2010)
E538	DECLARATION re <u>145</u> Answering Brief in Opposition,, <i>Declaration of Marcus T. Hall in Support of Plaintiff's Answering Brief in Opposition to Defendant's Motion For the Admission of Expert Testimony of John T. Goolkasian</i> by SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Exhibit A, # <u>2</u> Exhibit B, # <u>3</u> Exhibit C, # <u>4</u> Exhibit D, # <u>5</u> Exhibit E, # <u>6</u> Exhibit F, # <u>7</u> Exhibit G, # <u>8</u> Exhibit H, # <u>9</u> Exhibit I, # <u>10</u> Exhibit J, # <u>11</u> Exhibit K, # <u>12</u> Exhibit L, # <u>13</u> Exhibit M, # <u>14</u> Exhibit N, # <u>15</u> Certificate of Service)(Kraft, Denise) (Entered: 05/24/2010)
E539	Letter to The Honorable Sue L. Robinson from Denise Seastone Kraft, Esq. regarding [Proposed] Third Stipulation to Amend Scheduling Order - re <u>26</u> Scheduling Order,,,, (Attachments: # <u>1</u> Text of Proposed Order)(Kraft, Denise) (Entered: 05/25/2010). CORRECTING ENTRY: Stipulation attached to D.I. 147 has been deleted due to document being filed improperly. Counsel is advised to re-file document using the STIPULATION event code (lid) (Entered: 05/25/2010).
E540	STIPULATION [Proposed] Third Stipulation to Amend Scheduling Order re <u>26</u> Scheduling Order,,, <u>147</u> Letter by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (Entered: 05/25/2010). SO ORDERED- re <u>148</u> to Amend Scheduling Order. ORDER- Setting Scheduling Order Deadlines (Claims Construction Opening Brief due by 6/25/2010., Discovery due by 7/30/2010., Dispositive Motions due by 7/2/2010., Answering Brief due 7/16/2010., Reply Brief due 7/30/2010.). Signed by Judge Sue L. Robinson on 5/26/2010. (lid) (Entered: 05/26/2010)
E541	NOTICE OF SERVICE of Expert Reports of (1) Peter Moran, (2) John T. Goolkasian, (3) Robert Averback, and (4) Pascal Bellon by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 06/02/2010)
E542	NOTICE OF SERVICE of S.O.I.TEC Silicon On Insulator Technologies, S.A.'s Production 31 of CD-ROM Documents Bates Numbered SOIT 00476382 to SOIT 00476394 by SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 06/02/2010)

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FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)		APPLICANT(S): MORICEAU, et al.

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E543	NOTICE OF SERVICE of (1) Expert Report of Andrew Hirt; (2) Expert Report of John Bravman regarding Invalidity of United States Patent No. 5,834,812; and (3) Expert Report of John Bravman regarding Infringement by Defendant MEMC by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 06/02/2010)
E544	REPLY BRIEF IN SUPPORT OF <u>141</u> MOTION for Discovery MOTION FOR THE ADMISSION OF THE EXPERT TESTIMONY OF JOHN T. GOOLKASIAN RELATING TO THE CERTIFICATE OF CORRECTION FOR U.S. PATENT NO. 7,067,396 filed by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Exhibit 1, # <u>2</u> Exhibit 2, # <u>3</u> Exhibit 3, # <u>4</u> Exhibit 4, # <u>5</u> Exhibit 5, # <u>6</u> Exhibit 6)(Rogowski, Patricia) Modified on 6/4/2010 (lid). (Entered: 06/04/2010)
E545	NOTICE OF SERVICE of S.O.I.TEC Silicon On Insulator Technologies, S.A.'s Production 32 of CD-ROM Documents Bates Numbered SOIT 00476395 to SOIT 00476441 by SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 06/07/2010)
E546	STATEMENT re <u>148</u> Stipulation <i>Joint Claim Construction Statement</i> by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 06/14/2010)
E547	CLAIM Construction Chart by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 06/14/2010)
E548	NOTICE OF SERVICE of (1) S.O.I.TEC Silicon On Insulator Technologies, S.A.'s Production 33 of CD-ROM Documents Bates Numbered SOIT 00476442 to SOIT 00476456; and (2) S.O.I.TEC Silicon On Insulator Technologies, S.A.'s Production 33 Supplement including CD-ROM Documents Bates Numbered SOIT 00476442 to SOIT 00476456 (duplicates of Production 33) and SOIT 00476457 (Burg Translations, Inc. Certification) by SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 06/15/2010)
E549	SUR-REPLY BRIEF re <u>141</u> MOTION for Discovery MOTION FOR THE ADMISSION OF THE EXPERT TESTIMONY OF JOHN T. GOOLKASIAN RELATING TO THE CERTIFICATE OF CORRECTION FOR U.S. PATENT NO. 7,067,396 <i>Surreply by Plaintiffs to Motion by Defendant For The Admission of Expert Testimony of John T. Goolkasian</i> filed by SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 06/15/2010)

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FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
<b>LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT</b>	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)		APPLICANT(S): MORICEAU, et al.

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS
	(Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E550	DECLARATION re 157 Sur-Reply Brief, <i>Declaration of Marcus T. Hall in Support of Sureply by Plaintiffs to Motion by Defendant For The Admission of Expert Testimony of John T. Goolkasian</i> by SOITEC Silicon On Insulator Technologies SA. (Attachments: # 1 Exhibit A, # 2 Exhibit B, # 3 Exhibit C, # 4 Exhibit D, # 5 Certificate of Service)(Kraft, Denise) (Entered: 06/15/2010)
E551	NOTICE of Service of Videotaped Depositions for Dr. John C. Bravman and Andrew M. Hirt by MEMC Electronic Materials Inc. (Rogowski, Patricia) (Entered: 06/18/2010)
E552	STIPULATION Stipulated Motion for Leave to Exceed Page Limit Under Delaware L.R. 7.1.3 by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 06/21/2010); SO ORDERED- re 160 Stipulated Motion for Leave to Exceed Page Limit. Signed by Judge Sue L. Robinson on 6/22/2010. (lid) (Entered: 06/22/2010)
E553	NOTICE OF SERVICE of (1) Rebuttal Expert Report of Robert Averback; (2) Report on Characterization of Si Wafers by Transmission Electron Microscopy (Pascal Bellon); and (3) Rebuttal Expert Report of Peter Moran by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 06/22/2010)
E554	NOTICE OF SERVICE of Supplemental Expert Report of Peter Moran by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 06/22/2010)
E555	NOTICE OF SERVICE of Documents Marked MEMC0781986-MEMC0782012 by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 06/23/2010)
E556	NOTICE OF SERVICE of S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's: (1) Notice of Deposition of Dr. Peter Moran; (2) Notice of Deposition of Dr. Robert Averback; and (3) Notice of Deposition of Dr. Pascal Bellon by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 06/24/2010)
E557	NOTICE OF SERVICE of S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's List of Fact Witnesses by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 06/24/2010)
E558	NOTICE OF SERVICE of S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's: (1) Supplemental Expert Report of Andrew M. Hirt; and (2) Expert Report of John C. Bravman Regarding Non-infringement of U.S. Patent No. 5,834,812 by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 06/24/2010)

EXAMINER	DATE CONSIDERED
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FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)		APPLICANT(S): MORICEAU, et al.

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E559	CLAIM CONSTRUCTION OPENING BRIEF filed by MEMC Electronic Materials Inc.. (Attachments: # 1 Appendix DA0001-DA0006, # 2 Appendix DA0007-DA0032, # 3 Appendix DA0033-DA0072, # 4 Appendix DA0073-DA0112, # 5 Appendix DA0113-DA0152, # 6 Appendix DA0153-DA0192, # 7 Appendix DA0193-DA0232, # 8 Appendix DA0233-DA0272, # 9 Appendix DA0273-DA0312, # 10 Appendix DA0313-DA0352, # 11 Appendix DA0353-DA0392, # 12 Appendix DA0393-DA0432, # 13 Appendix DA0433-DA0472, # 14 Appendix DA0473-DA0512, # 15 Appendix DA0513-DA0521, # 16 Appendix DA0522-DA0545, # 17 Appendix SEALED - DA0546-DA0551, # 18 Appendix DA0552-DA0563, # 19 Appendix SEALED - DA0564-DA0566, # 20 Appendix DA0567-DA0573, # 21 Appendix SEALED - DA0574-DA0599, # 22 Appendix DA0600-DA0604, # 23 Appendix DA0605-DA0609, # 24 Appendix DA0610-DA0625, # 25 Appendix DA0626-0634, # 26 Appendix DA0635, # 27 Appendix DA0636-DA0652, # 28 Appendix SEALED - DA0653-DA0657, # 29 Appendix DA0658-DA0667, # 30 Appendix DA0668-DA0670, # 31 Appendix DA0671-DA0678, # 32 Appendix DA0679-DA0687, # 33 Appendix DA0688-DA0696, # 34 Appendix SEALED - DA0697-DA0705, # 35 Appendix SEALED - DA0706-DA0711, # 36 Appendix SEALED - DA0712-DA0714, # 37 Appendix DA0715-DA0717, # 38 Appendix DA0718-DA0719, # 39 Appendix DA0720-DA0722, # 40 Appendix DA0723-DA0732, # 41 Appendix DA0733-DA0740, # 42 Appendix DA0741-DA0749, # 43 Appendix DA0750-DA0769, # 44 Appendix DA0770-DA0781)(Rogowski, Patricia) (Entered: 06/25/2010)
E560	CLAIM CONSTRUCTION OPENING BRIEF <i>Plaintiffs S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's Opening Claim Construction Brief</i> filed by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 06/25/2010)
E561	DECLARATION re 168 Claim Construction Opening Brief, <i>Declaration of Marcus T. Hall in Support of Plaintiffs S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's Opening Claim Construction Brief</i> by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 06/25/2010)
E562	SEALED EXHIBIT re 169 Declaration, <i>Exhibit A (Filed Under Seal) to Declaration of Marcus T. Hall in Support of Plaintiffs S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's Opening Claim Construction Brief</i> by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 06/25/2010)

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FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)		APPLICANT(S): MORICEAU, et al.

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E563	SEALED EXHIBIT re <u>169</u> Declaration, <i>Exhibit B (Filed Under Seal) to Declaration of Marcus T. Hall in Support of Plaintiffs S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's Opening Claim Construction Brief</i> by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 06/25/2010)
E564	SEALED EXHIBIT re <u>169</u> Declaration, <i>Exhibit C (Filed Under Seal) to Declaration of Marcus T. Hall in Support of Plaintiffs S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's Opening Claim Construction Brief</i> by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 06/25/2010)
E565	NOTICE of filing the following document(s) in paper format: Joint Appendix of Exhibits to Opening and Answering Claim Construction Briefs (1) Vol. I - JA0001 to JA0533; (2) Vol. II - JA0534 to JA0930; (3) Vol. III - JA0931 to JA1502; (4) Vol. IV - JA1503 to JA1510 (Filed Under Seal); (5) Vol. V - JA1511 to JA2089; and (6) Vol. VI - JA2090 to JA2557. Original document(s) to be filed with the Clerk's Office. Notice filed by Denise Seastone Kraft on behalf of Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 06/25/2010); CORRECTING ENTRY: Docket clerk deleted appendices to D.I. 167 due to documents being filed improperly. Counsel is advised to re-file appendices separately using the APPENDIX event code. Counsel is also advised that sealed documents may not be filed with public view documents. (lid) (Entered: 06/28/2010)
E566	(Document too large to file in pdf format, will file at later date by Express Mail). APPENDIX re <u>167</u> Claim Construction Opening Brief,,,,, by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Appendix DA-0001 - DA-0006, # <u>2</u> Appendix DA-0007 - DA-0032, # <u>3</u> Appendix DA-0033 - DA-0072, # <u>4</u> Appendix DA-0073 - DA-0112, # <u>5</u> Appendix DA-0113 - DA-0152, # <u>6</u> Appendix DA-0153 - DA-0192, # <u>7</u> Appendix DA-0193 - DA-0232, # <u>8</u> Appendix DA-0233 - DA-0272, # <u>9</u> Appendix DA-0273 - DA-0312, # <u>10</u> Appendix DA-0313 - DA-0352, # <u>11</u> Appendix DA-0353 - DA-0392, # <u>12</u> Appendix DA-0393 - DA-0432, # <u>13</u> Appendix DA-0433 - DA-0472, # <u>14</u> Appendix DA-0473 - DA-0512, # <u>15</u> Appendix DA-0513 - DA-0521)(Rogowski, Patricia) (Entered: 06/28/2010)
E567	SEALED APPENDIX re <u>167</u> Claim Construction Opening Brief,,,,, by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 06/28/2010)

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FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)		APPLICANT(S): MORICEAU, et al.

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E568	NOTICE OF SERVICE of S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's Production 34 of CD-ROM Documents Bates Numbered SOIT 00476458 to SOIT 00476602 by SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 06/28/2010)
E569	REDACTED VERSION of <u>175</u> Appendix by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Appendix DA0522-DA0545, # <u>2</u> Appendix DA0546-DA0551, # <u>3</u> Appendix DA0552-DA0563, # <u>4</u> Appendix DA0564-DA0566, # <u>5</u> Appendix DA0567-DA0573, # <u>6</u> Appendix DA0574-DA0599, # <u>7</u> Appendix DA0600-DA0604, # <u>8</u> Appendix DA0605-DA0609, # <u>9</u> Appendix DA0610-DA0625, # <u>10</u> Appendix DA0626-DA0634, # <u>11</u> Appendix DA0635, # <u>12</u> Appendix DA0636-DA0652, # <u>13</u> Appendix DA0653-DA0657, # <u>14</u> Appendix DA0658-DA0667, # <u>15</u> Appendix DA0668-DA0670, # <u>16</u> Appendix DA0671-DA0678, # <u>17</u> Appendix DA0679-DA0687, # <u>18</u> Appendix DA0688-DA0696, # <u>19</u> Appendix DA0697-DA0705, # <u>20</u> Appendix DA0706-DA-0711, # <u>21</u> Appendix DA0712-DA0714, # <u>22</u> Appendix DA0715-DA0717, # <u>23</u> Appendix DA0718-DA0719, # <u>24</u> Appendix DA0720-DA0722, # <u>25</u> Appendix DA0723-DA0732, # <u>26</u> Appendix DA0733-DA0740, # <u>27</u> Appendix DA0741-DA0749, # <u>28</u> Appendix DA0750-DA0769, # <u>29</u> Appendix DA0770-DA0781, # <u>30</u> Certificate of Service)(Rogowski, Patricia) (Entered: 06/28/2010)
E570	(Document too large to file in pdf format, will file at later date by Express Mail). NOTICE of filing the following document(s) in paper format: Joint Appendix of Exhibits to Opening and Answering Claim Construction Briefs (1) Vol. I - JA0001 to JA0533. APPENDIX VOL I. re 173 Notice of Filing Paper Documents(OVERSIZED DOCUMENT, ITEM ON FILE IN THE CLERKS OFFICE). (lid) (Entered: 06/28/2010).
E571	(Document too large to file in pdf format, will file at later date by Express Mail). NOTICE of filing the following document(s) in paper format: Joint Appendix of Exhibits to Opening and Answering Claim Construction Briefs (2) Vol. II - JA0534 to JA0930. APPENDIX VOL II. re 173 Notice of Filing Paper Documents(OVERSIZED DOCUMENT, ITEM ON FILE IN THE CLERKS OFFICE). (lid) (Entered: 06/28/2010).
E572	(Document too large to file in pdf format, will file at later date by Express Mail). NOTICE of filing the following document(s) in paper format: Joint Appendix of Exhibits to Opening and Answering Claim Construction Briefs (3) Vol. III - JA0931 to JA1502. APPENDIX VOL III. re 173 Notice of Filing Paper Documents(OVERSIZED DOCUMENT, ITEM ON FILE IN THE CLERKS OFFICE) (lid) (Entered: 06/28/2010).

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<b>LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT</b>	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)	APPLICANT(S): MORICEAU, et al.	

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS
	(Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E573	(Document too large to file in pdf format, will file at later date by Express Mail). NOTICE of filing the following document(s) in paper format: Joint Appendix of Exhibits to Opening and Answering Claim Construction Briefs (4) Vol. IV – JA1503 to JA1510. APPENDIX VOL IV. re 173 Notice of Filing Paper Documents, (OVERSIZED DOCUMENT, ITEM ON FILE IN THE CLERKS OFFICE) (lid) (Entered: 06/28/2010).
E574	(Document too large to file in pdf format, will file at later date by Express Mail). NOTICE of filing the following document(s) in paper format: Joint Appendix of Exhibits to Opening and Answering Claim Construction Briefs (5) Vol. V – JA1511 to JA2089.
E575	(Document too large to file in pdf format, will file at later date by Express Mail). Vol. VI - JA2090 to JA2557. Original document(s) to be filed with the Clerk's Office. Notice filed by Denise Seastone Kraft on behalf of Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 06/25/2010).
E576	SEALED APPENDIX re 168 Claim Construction Opening Brief, <i>Joint Appendix of Exhibits to Opening and Answering Claim Construction Briefs Volume IV of VI - Filed Under Seal</i> by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 06/28/2010)
E577	NOTICE OF SERVICE of S.O.I.TEC Silicon on Insulator Technologies, S.A.'s and Commissariat a L'Energie Atomique's List of Rebuttal Fact Witnesses by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 06/30/2010)
E578	NOTICE OF SERVICE of Amended Notice of Videotaped Deposition of Dr. John C. Bravman by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 06/30/2010)
E579	MOTION in Limine <i>SOITEC/CEA Parties' Motion to Exclude The Expert Report of Dr. Pascal Bellon and Any Related Testimony</i> - filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # 1 Text of Proposed Order, # 2 Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
E580	MOTION for Partial Summary Judgment of <i>Invalidity of the Asserted Aspar Patent Claims</i> - filed by MEMC Electronic Materials Inc.. (Attachments: # 1 Text of Proposed Order, # 2 Certificate of Service)(Rogowski, Patricia) (Entered: 07/02/2010)
E581	OPENING BRIEF in Support re 186 MOTION in Limine <i>SOITEC/CEA Parties' Motion to Exclude The Expert Report of Dr. Pascal Bellon and Any Related Testimony</i> filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. Answering Brief/Response due date per Local Rules is 7/19/2010. (Attachments: # 1 Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)

EXAMINER	DATE CONSIDERED
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EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
<b>LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT</b>	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)	APPLICANT(S): MORICEAU, et al.	

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E582	OPENING BRIEF in Support re <u>187</u> MOTION for Partial Summary Judgment of <i>Invalidity of the Asserted Aspar Patent Claims</i> filed by MEMC Electronic Materials Inc.. Answering Brief/Response due date per Local Rules is 7/19/2010. (Rogowski, Patricia) (Entered: 07/02/2010)
E583	SEALED APPENDIX re <u>189</u> Opening Brief in Support, by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Table of Contents, # <u>2</u> Certificate of Service)(Rogowski, Patricia) (Entered: 07/02/2010)
E584	<b>(Document too large to file in pdf format, will file at later date by Express Mail).</b> APPENDIX re <u>186</u> MOTION in Limine <i>SOITEC/CEA Parties' Motion to Exclude The Expert Report of Dr. Pascal Bellon and Any Related Testimony Plaintiffs' Omnibus Appendix to Daubert Motion and Motions For Partial Summary Judgment Filed on July 2, 2010</i> by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Appendix Vol. II of XIX, # <u>2</u> Appendix Vol. III of XIX, # <u>3</u> Appendix Vol. IV of XIX, # <u>4</u> Appendix Vol. V of XIX, # <u>5</u> Appendix Vol. VII of XIX, # <u>6</u> Appendix Vol. IX of XIX, # <u>7</u> Appendix Vol. XI of XIX, # <u>8</u> Appendix Vol. XII of XIX, # <u>9</u> Appendix Vol. XIII of XIX, # <u>10</u> Appendix Vol. XIV of XIX, # <u>11</u> Appendix Vol. XV of XIX, # <u>12</u> Appendix Vol. XVI of XIX, # <u>13</u> Appendix Vol. XVIII of XIX, # <u>14</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
E585	SEALED APPENDIX re <u>186</u> MOTION in Limine <i>SOITEC/CEA Parties' Motion to Exclude The Expert Report of Dr. Pascal Bellon and Any Related Testimony Plaintiffs' Omnibus Appendix to Daubert Motion and Motions For Partial Summary Judgment Filed on July 2, 2010 - Vol. VI of XIX (FILED UNDER SEAL)</i> by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
E586	SEALED APPENDIX re <u>186</u> MOTION in Limine <i>SOITEC/CEA Parties' Motion to Exclude The Expert Report of Dr. Pascal Bellon and Any Related Testimony Plaintiffs' Omnibus Appendix to Daubert Motion and Motions For Partial Summary Judgment Filed on July 2, 2010 - Vol. VIII of XIX (FILED UNDER SEAL)</i> by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
E587	SEALED APPENDIX re <u>186</u> MOTION in Limine <i>SOITEC/CEA Parties' Motion to Exclude The Expert Report of Dr. Pascal Bellon and Any Related Testimony Plaintiffs' Omnibus Appendix to Daubert Motion and Motions For Partial Summary Judgment Filed on July 2, 2010 - Vol. X of XIX (FILED UNDER SEAL)</i> by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)

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(use several sheets if necessary)		APPLICANT(S): MORICEAU, et al.

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS
	(Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E588	SEALED APPENDIX re <u>186</u> MOTION in Limine <i>SOITEC/CEA Parties' Motion to Exclude The Expert Report of Dr. Pascal Bellon and Any Related Testimony Plaintiffs' Omnibus Appendix to Daubert Motion and Motions For Partial Summary Judgment Filed on July 2, 2010 - Vol. XVII of XIX (FILED UNDER SEAL)</i> by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
E589	SEALED APPENDIX re <u>186</u> MOTION in Limine <i>SOITEC/CEA Parties' Motion to Exclude The Expert Report of Dr. Pascal Bellon and Any Related Testimony Plaintiffs' Omnibus Appendix to Daubert Motion and Motions For Partial Summary Judgment Filed on July 2, 2010 - Vol. XIX of XIX (FILED UNDER SEAL)</i> by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
E590	SEALED MOTION for Summary Judgment <i>SOITEC/CEA Parties' Motion For Summary Judgment: Non-Infringement (FILED UNDER SEAL)</i> - filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
E591	SEALED OPENING BRIEF in Support re <u>197</u> SEALED MOTION for Summary Judgment <i>SOITEC/CEA Parties' Motion For Summary Judgment: Non-Infringement (FILED UNDER SEAL)</i> SEALED MOTION for Summary Judgment <i>SOITEC/CEA Parties' Motion For Summary Judgment: Non-Infringement (FILED UNDER SEAL)</i> filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. Answering Brief/Response due date per Local Rules is 7/19/2010. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
E592	MOTION for Summary Judgment of <i>Non-Infringement</i> - filed by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Text of Proposed Order, # <u>2</u> Certificate of Service)(Rogowski, Patricia) (Entered: 07/02/2010)
E593	SEALED OPENING BRIEF in Support re <u>199</u> MOTION for Summary Judgment of <i>Non-Infringement</i> filed by MEMC Electronic Materials Inc.. Answering Brief/Response due date per Local Rules is 7/19/2010. (Attachments: # <u>1</u> Certificate of Service)(Rogowski, Patricia) (Entered: 07/02/2010)
E594	SEALED APPENDIX re <u>200</u> Opening Brief in Support, by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Table of Contents, # <u>2</u> Certificate of Service)(Rogowski, Patricia) (Entered: 07/02/2010)
E595	MOTION for Partial Summary Judgment <i>SOITEC/CEA Parties Motion For Partial Summary Judgment That The Patents in Suit Satisfy The Written Description Requirement</i> - filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
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<b>LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT</b>	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)		APPLICANT(S): MORICEAU, et al.

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E596	OPENING BRIEF in Support re <u>202</u> MOTION for Partial Summary Judgment <i>SOITEC/CEA Parties Motion For Partial Summary Judgment That The Patents in Suit Satisfy The Written Description Requirement</i> filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc. Answering Brief/Response due date per Local Rules is 7/19/2010. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
E597	MOTION for Partial Summary Judgment <i>Plaintiffs' Motion For Partial Summary Judgment That The Certificate of Correction For the '396 Patent is Valid</i> - filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
E598	OPENING BRIEF in Support re <u>204</u> MOTION for Partial Summary Judgment <i>Plaintiffs' Motion For Partial Summary Judgment That The Certificate of Correction For the '396 Patent is Valid</i> filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. Answering Brief/Response due date per Local Rules is 7/19/2010. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
E599	MOTION for Partial Summary Judgment <i>SOITEC/CEA Parties' Motion For Partial Summary Judgment That The Aspar Patents Are Not Invalid For Inequitable Conduct</i> - filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Text of Proposed Order, # <u>2</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
E600	OPENING BRIEF in Support re <u>206</u> MOTION for Partial Summary Judgment <i>SOITEC/CEA Parties' Motion For Partial Summary Judgment That The Aspar Patents Are Not Invalid For Inequitable Conduct</i> filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. Answering Brief/Response due date per Local Rules is 7/19/2010. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
E601	MOTION for Partial Summary Judgment <i>Plaintiffs' Motion For Partial Summary Judgment That The Bruel Patent Does Not Anticipate The Aspar Patents</i> - filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Text of Proposed Order, # <u>2</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
E602	OPENING BRIEF in Support re <u>208</u> MOTION for Partial Summary Judgment <i>Plaintiffs' Motion For Partial Summary Judgment That The Bruel Patent Does Not Anticipate The Aspar Patents</i> filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. Answering Brief/Response due date per Local Rules is 7/19/2010. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
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(use several sheets if necessary)	APPLICANT(S): MORICEAU, et al.	

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E603	MOTION for Partial Summary Judgment <i>SOITEC's Motion For Partial Summary Judgment of Invalidity of United States Patent No. 5,834,812 For Lack of Enablement</i> - filed by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Text of Proposed Order, # <u>2</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
E604	OPENING BRIEF in Support re <u>210</u> MOTION for Partial Summary Judgment <i>SOITEC's Motion For Partial Summary Judgment of Invalidity of United States Patent No. 5,834,812 For Lack of Enablement</i> filed by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc. Answering Brief/Response due date per Local Rules is 7/19/2010. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
E605	MOTION for Partial Summary Judgment <i>SOITEC's Motion For Partial Summary Judgment For Invalidity of Asserted Claims of United States Patent No. 5,834,812 in View of Prior Art</i> - filed by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Text of Proposed Order, # <u>2</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
E606	MOTION for Partial Summary Judgment <i>That the Best Mode Requirement is Satisfied for the Claims of the '009 and '396 Patents</i> - filed by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Text of Proposed Order, # <u>2</u> Certificate of Service)(Reed, John) (Entered: 07/02/2010)
E607	OPENING BRIEF in Support re <u>212</u> MOTION for Partial Summary Judgment <i>SOITEC's Motion For Partial Summary Judgment For Invalidity of Asserted Claims of United States Patent No. 5,834,812 in View of Prior Art</i> filed by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc. Answering Brief/Response due date per Local Rules is 7/19/2010. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/02/2010)
E608	OPENING BRIEF in Support re <u>213</u> MOTION for Partial Summary Judgment <i>That the Best Mode Requirement is Satisfied for the Claims of the '009 and '396 Patents</i> filed by SOITEC Silicon On Insulator Technologies SA. Answering Brief/Response due date per Local Rules is 7/19/2010. (Attachments: # <u>1</u> Certificate of Service)(Reed, John) (Entered: 07/02/2010)
E609	CORRECTING ENTRY: Per request of counsel, D.I. number 216 has been deleted and will be re-filed at a later time (lid) (Entered: 07/07/2010)
E610	CORRECTING ENTRY: Per request of counsel, D.I. number 217 has been deleted and will be re-filed at a later time (lid) (Entered: 07/07/2010)

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LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)		APPLICANT(S): MORICEAU, et al.

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E611	REDACTED VERSION of <u>200</u> Opening Brief in Support, by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Certificate of Service)(Rogowski, Patricia) (Entered: 07/07/2010); CORRECTING ENTRY: Per request of counsel, D.I. numbers <b>216</b> and <b>217</b> have been deleted and will be re-filed at a later time (lid) (Entered: 07/07/2010)
E612	REDACTED VERSION of <u>201</u> Appendix by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Appendix MA0001 - MA0004, # <u>2</u> Appendix MA0005 - MA0010, # <u>3</u> Appendix MA0011 - MA0016, # <u>4</u> Appendix MA0017 - MA0020, # <u>5</u> Appendix MA0021 - MA0029, # <u>6</u> Appendix MA0030 - MA0045, # <u>7</u> Appendix MA0046 - MA0052, # <u>8</u> Appendix MA0053 - MA0078, # <u>9</u> Appendix MA0079 - MA0092, # <u>10</u> Appendix MA0093 - MA0129, # <u>11</u> Appendix MA0130 - MA0148, # <u>12</u> Appendix MA0149 - MA0160, # <u>13</u> Appendix MA0161 - MA0163, # <u>14</u> Appendix MA0164 - MA0167, # <u>15</u> Appendix MA0168 - MA0172, # <u>16</u> Appendix MA0173 - MA0183, # <u>17</u> Appendix MA0184 - MA0196, # <u>18</u> Appendix MA0197 - MA0207, # <u>19</u> Appendix MA0208 - MA0241, # <u>20</u> Appendix MA0242 - MA0245, # <u>21</u> Appendix MA0246 - MA0249, # <u>22</u> Appendix MA0250 - MA0252, # <u>23</u> Appendix MA0253 - MA0265, # <u>24</u> Appendix MA0266 - MA0281, # <u>25</u> Appendix MA0282 - MA0312, # <u>26</u> Appendix MA0313 - MA0359, # <u>27</u> Appendix MA0360 - MA0365, # <u>28</u> Appendix MA0366, # <u>29</u> Appendix MA0367 - MA0400, # <u>30</u> Appendix MA0401 - MA0474, # <u>31</u> Appendix MA0475 - MA0483, # <u>32</u> Certificate)(Rogowski, Patricia) (Entered: 07/07/2010)

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EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS
	(Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E613	REDACTED VERSION of <u>190</u> Appendix by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Appendix MA0484 - MA0489, # <u>2</u> Appendix MA0490 - MA0515, # <u>3</u> Appendix MA0516 - MA0534, # <u>4</u> Appendix MA0535 - MA0541, # <u>5</u> Appendix MA0542 - MA0550, # <u>6</u> Appendix MA0551 - MA0561, # <u>7</u> Appendix MA0562 - MA0564, # <u>8</u> Appendix MA0565 - MA0569, # <u>9</u> Appendix MA0570 - MA0574, # <u>10</u> Appendix MA0575 - MA0576, # <u>11</u> Appendix MA0577 - MA0601, # <u>12</u> Appendix MA0602 - MA0603, # <u>13</u> Appendix MA0604 - MA0605, # <u>14</u> Appendix MA0606 - MA0609, # <u>15</u> Appendix MA0610 - MA0612, # <u>16</u> Appendix MA0613 - MA0625, # <u>17</u> Appendix MA0626 - MA0628, # <u>18</u> Appendix MA0629 - MA0630, # <u>19</u> Appendix MA0631 - MA0653, # <u>20</u> Appendix MA0654 - MA0685, # <u>21</u> Appendix MA0686 - MA0701, # <u>22</u> Appendix MA0702 - MA0732, # <u>23</u> Appendix MA0733 - MA0742, # <u>24</u> Appendix MA0743 - MA0750, # <u>25</u> Appendix MA0751 - MA0766, # <u>26</u> Appendix MA0767 - MA0772, # <u>27</u> Appendix MA0773 - MA0780, # <u>28</u> Appendix MA0781 - MA0807, # <u>29</u> Appendix MA0808 - MA0824, # <u>30</u> Appendix MA0825 - MA0831.1, # <u>31</u> Appendix MA0832 - MA0838, # <u>32</u> Appendix MA0839 - MA0844, # <u>33</u> Appendix MA0845 - MA0858, # <u>34</u> Appendix MA0859 - MA0868, # <u>35</u> Appendix MA0869 - MA0877, # <u>36</u> Appendix MA0878 - MA0884, # <u>37</u> Appendix MA0885 - MA0887, # <u>38</u> Appendix MA0888 - MA0891, # <u>39</u> Appendix MA0892 - MA0909, # <u>40</u> Appendix MA0910 - MA0931, # <u>41</u> Certificate of Service)(Rogowski, Patricia) (Entered: 07/07/2010)
E614	REDACTED VERSION of <u>198</u> Opening Brief in Support, <i>SOITEC/CEA Parties' Opening Brief In Support Of Motion For Summary Judgment: Non-Infringement</i> by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (Entered: 07/08/2010)
E615	REDACTED VERSION of <u>197</u> SEALED MOTION for Summary Judgment <i>SOITEC/CEA Parties' Motion For Summary Judgment: Non-Infringement (FILED UNDER SEAL)</i> SEALED MOTION for Summary Judgment <i>SOITEC/CEA Parties' Motion For Summary Judgment: Non-Infringement (FILED UNDER SEAL)</i> <i>SOITEC/CEA Parties' Motion For Summary Judgment: Non-Infringement</i> by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (Entered: 07/08/2010)
E616	REDACTED VERSION of <u>192</u> Appendix, <i>Plaintiffs' Omnibus Appendix to Daubert Motion And Motions For Partial Summary Judgment Filed on July 2, 2010 - Volume VI of XIX</i> by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (Entered: 07/09/2010)
E617	REDACTED VERSION of <u>193</u> Appendix, <i>Plaintiffs' Omnibus Appendix to Daubert Motion And Motions For Partial Summary Judgment Filed on July 2, 2010 - Volume VIII of XIX</i> by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (Entered: 07/09/2010)
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(use several sheets if necessary)		APPLICANT(S): MORICEAU, et al.

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E618	REDACTED VERSION of <u>194</u> Appendix, <i>Plaintiffs' Omnibus Appendix to Daubert Motion And Motions For Partial Summary Judgment Filed on July 2, 2010 - Volume X of XIX</i> by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (Entered: 07/09/2010)
E619	REDACTED VERSION of <u>195</u> Appendix, <i>Plaintiffs' Omnibus Appendix to Daubert Motion And Motions For Partial Summary Judgment Filed on July 2, 2010 - Volume XVII of XIX</i> by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (Entered: 07/09/2010)
E620	REDACTED VERSION of <u>196</u> Appendix, <i>Plaintiffs' Omnibus Appendix to Daubert Motion And Motions For Partial Summary Judgment Filed on July 2, 2010 - Volume XIX of XIX</i> by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Kraft, Denise) (Entered: 07/09/2010)
E621	CLAIM CONSTRUCTION ANSWERING BRIEF re <u>168</u> Claim Construction Opening Brief, filed by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Certificate of Service)(Rogowski, Patricia) (Entered: 07/09/2010)
E622	APPENDIX re <u>228</u> Claim Construction Answering Brief by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Appendix DA0782 - DA0783, # <u>2</u> Appendix DA0784 - DA0785, # <u>3</u> Appendix DA0786, # <u>4</u> Appendix DA0787 - DA0810, # <u>5</u> Appendix DA0811 - DA0834, # <u>6</u> Appendix DA0835 - DA0845, # <u>7</u> Appendix DA0846 - DA0855, # <u>8</u> Certificate of Service)(Rogowski, Patricia) (Entered: 07/09/2010)
E623	CLAIM CONSTRUCTION ANSWERING BRIEF re <u>168</u> Claim Construction Opening Brief, <u>228</u> Claim Construction Answering Brief <i>Plaintiffs S.O.I.TEC On Insulator Technologies, S.A. And Commissariat A Energie Atomique's Answering Claim Construction Brief</i> filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/09/2010)
E624	APPENDIX re <u>230</u> Claim Construction Answering Brief, <i>Appendix to Plaintiffs S.O.I.TEC On Insulator Technologies, S.A. And Commissariat A Energie Atomique's Answering Claim Construction Brief</i> by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Appendix PA-0001 - PA-0050, # <u>2</u> Appendix PA-0051 - PA-0083, # <u>3</u> Certificate of Service)(Kraft, Denise) (Entered: 07/09/2010)
E625	REDACTED VERSION of <u>183</u> Appendix, <i>Joint Appendix of Exhibits to Opening and Answering Claim Construction Briefs Volume IV of VI</i> by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Kraft, Denise) (Entered: 07/12/2010)

EXAMINER	DATE CONSIDERED
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FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)		APPLICANT(S): MORICEAU, et al.

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E626	REDACTED VERSION of <u>170</u> Exhibit to a Document, <i>Exhibit A to Declaration of Marcus T. Hall in Support of Plaintiffs S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's Opening Claim Construction Brief</i> by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA. (Kraft, Denise) (Entered: 07/12/2010)
E627	REDACTED VERSION of <u>171</u> Exhibit to a Document, <i>Exhibit B to Declaration of Marcus T. Hall in Support of Plaintiffs S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's Opening Claim Construction Brief</i> by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA. (Kraft, Denise) (Entered: 07/12/2010)
E628	REDACTED VERSION of <u>172</u> Exhibit to a Document, <i>Exhibit C to Declaration of Marcus T. Hall in Support of Plaintiffs S.O.I.TEC Silicon on Insulator Technologies, S.A. and Commissariat a L'Energie Atomique's Opening Claim Construction Brief</i> by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA. (Kraft, Denise) (Entered: 07/12/2010)
E629	Letter to The Honorable Sue L. Robinson from Denise Seastone Kraft, Esq. regarding Courtesy CD-ROM copies of: (1) Plaintiffs' Answering Claim Construction Brief and Appendix; and (2) Plaintiffs' Daubert Motion; Plaintiffs' Motions For Partial Summary Judgment; and Plaintiffs' Omnibus Appendix to Daubert Motion and Motions For Partial Summary Judgment. (Kraft, Denise) (Entered: 07/12/2010)
E630	NOTICE OF SERVICE of Re-Notice of Deposition of Dr. Peter Moran on behalf of S.O.I.TEC Silicon on Insulator Technologies, S.A., Commissariat a L'Energie Atomique, and SOITEC U.S.A., Inc. by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/13/2010)
E631	Fourth STIPULATION To Amend Scheduling Order re <u>26</u> Scheduling Order,,, by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 07/15/2010)
E632	ANSWERING BRIEF in Opposition re <u>186</u> MOTION in Limine <i>SOITEC/CEA Parties' Motion to Exclude The Expert Report of Dr. Pascal Bellon and Any Related Testimony</i> filed by MEMC Electronic Materials Inc..Reply Brief due date per Local Rules is 7/29/2010. (Rogowski, Patricia) (Entered: 07/19/2010)
E633	SEALED APPENDIX re <u>239</u> Answering Brief in Opposition, by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Table of Contents, # <u>2</u> Certificate of Service)(Rogowski, Patricia) (Entered: 07/19/2010)
E634	SEALED ANSWERING BRIEF in Opposition re <u>213</u> MOTION for Partial Summary Judgment <i>That the Best Mode Requirement is Satisfied for the Claims of the '009 and '396 Patents</i> filed by MEMC Electronic Materials Inc..Reply Brief due date per Local Rules is 7/29/2010. (Rogowski, Patricia) (Entered: 07/19/2010)
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E635	ANSWERING BRIEF in Opposition re <u>208</u> MOTION for Partial Summary Judgment <i>Plaintiffs' Motion For Partial Summary Judgment That The Bruel Patent Does Not Anticipate The Aspar Patents</i> filed by MEMC Electronic Materials Inc..Reply Brief due date per Local Rules is 7/29/2010. (Rogowski, Patricia) (Entered: 07/19/2010)
E636	ANSWERING BRIEF in Opposition re <u>202</u> MOTION for Partial Summary Judgment <i>SOITEC/CEA Parties Motion For Partial Summary Judgment That The Patents in Suit Satisfy The Written Description Requirement</i> filed by MEMC Electronic Materials Inc..Reply Brief due date per Local Rules is 7/29/2010. (Rogowski, Patricia) (Entered: 07/19/2010)
E637	ANSWERING BRIEF in Opposition re <u>204</u> MOTION for Partial Summary Judgment <i>Plaintiffs' Motion For Partial Summary Judgment That The Certificate of Correction For the '396 Patent is Valid</i> filed by MEMC Electronic Materials Inc..Reply Brief due date per Local Rules is 7/29/2010. (Rogowski, Patricia) (Entered: 07/19/2010)
E638	ANSWERING BRIEF in Opposition re <u>210</u> MOTION for Partial Summary Judgment <i>SOITEC's Motion For Partial Summary Judgment of Invalidity of United States Patent No. 5,834,812 For Lack of Enablement</i> filed by MEMC Electronic Materials Inc..Reply Brief due date per Local Rules is 7/29/2010. (Rogowski, Patricia) (Entered: 07/19/2010)
E639	ANSWERING BRIEF in Opposition re <u>212</u> MOTION for Partial Summary Judgment <i>SOITEC's Motion For Partial Summary Judgment For Invalidity of Asserted Claims of United States Patent No. 5,834,812 in View of Prior Art</i> filed by MEMC Electronic Materials Inc..Reply Brief due date per Local Rules is 7/29/2010. (Rogowski, Patricia) (Entered: 07/19/2010)
E640	SEALED ANSWERING BRIEF in Opposition re <u>187</u> MOTION for Partial Summary Judgment of Invalidity of the Asserted Aspar Patent <i>Claims Plaintiffs' Answering Brief In Opposition To Defendant's Motion For Partial Summary Judgment Of Invalidity Of The Asserted Aspar Claims - FILED UNDER SEAL</i> filed by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA.Reply Brief due date per Local Rules is 7/29/2010. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/19/2010)
E641	APPENDIX re <u>247</u> Answering Brief in Opposition,, <i>Appendix To Plaintiffs' Answering Brief In Opposition To Defendant's Motion For Partial Summary Judgment Of Invalidity Of The Asserted Aspar Claims (PA-1103 - PA-1156)</i> by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Exhibit PA-1103 - PA-1109 - FILED UNDER SEAL, # <u>2</u> Exhibit PA-1110 - PA-1118 - FILED UNDER SEAL, # <u>3</u> Exhibit PA-1119 - PA-1130 - FILED UNDER SEAL, # <u>4</u> Exhibit PA-1131 - PA-1143 - FILED UNDER SEAL, # <u>5</u> Exhibit PA-1144 - PA-1156, # <u>6</u> Certificate of Service)(Kraft, Denise) (Entered: 07/19/2010)
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(use several sheets if necessary)		APPLICANT(S): MORICEAU, et al.

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E642	SEALED ANSWERING BRIEF in Opposition re <u>197</u> SEALED MOTION for Summary Judgment <i>SOITEC/CEA Parties' Motion For Summary Judgment: Non-Infringement (FILED UNDER SEAL)</i> SEALED MOTION for Summary Judgment <i>SOITEC/CEA Parties' Motion For Summary Judgment: Non-Infringement (FILED UNDER SEAL)</i> filed by MEMC Electronic Materials Inc..Reply Brief due date per Local Rules is 7/29/2010. (Rogowski, Patricia) (Entered: 07/19/2010)
E643	SEALED ANSWERING BRIEF in Opposition re <u>199</u> MOTION for Summary Judgment of <i>Non-Infringement Soitec's Brief in Opposition to Defendant's Motion For Summary Judgment of Non-Infringement</i> filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA.Reply Brief due date per Local Rules is 7/29/2010. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/19/2010)
E644	SEALED APPENDIX re <u>250</u> Answering Brief in Opposition, <i>Appendix to Plaintiffs' Answering Brief in Opposition to Defendant's Motion For Summary Judgment of Non-Infringement</i> by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Exhibit PA-1157 - PA-1159 FILED UNDER SEAL, # <u>2</u> Exhibit PA-1160 - PA-1165 FILED UNDER SEAL, # <u>3</u> Exhibit PA-1166 - PA-1168 FILED UNDER SEAL, # <u>4</u> Exhibit PA-1169 - PA-1185 FILED UNDER SEAL, # <u>5</u> Exhibit PA-1186 - PA-1189)(Kraft, Denise) (Entered: 07/19/2010)
E645	APPENDIX re <u>250</u> Answering Brief in Opposition, <i>Appendix to Plaintiffs' Answering Brief in Opposition to Defendant's Motion For Summary Judgment of Non-Infringement</i> by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Exhibit PA-1190 - PA-1191, # <u>2</u> Certificate of Service)(Kraft, Denise) (Entered: 07/19/2010)
E646	SEALED ANSWERING BRIEF in Opposition re <u>206</u> MOTION for Partial Summary Judgment <i>SOITEC/CEA Parties' Motion For Partial Summary Judgment That The Aspar Patents Are Not Invalid For Inequitable Conduct</i> filed by MEMC Electronic Materials Inc..Reply Brief due date per Local Rules is 7/29/2010. (Rogowski, Patricia) (Entered: 07/19/2010); CORRECTING ENTRY: Docket clerk deleted sealed exhibits 1-4 attached to D.I. 248 due to documents being filed improperly. Counsel is advised that sealed and public documents may not be filed together and to re-file documents using the EXHIBIT TO A DOCUMENT event code indicating that documents are under seal. (lid) (Entered: 07/20/2010)

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FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)		APPLICANT(S): MORICEAU, et al.

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E647	SEALED APPENDIX re <u>247</u> Answering Brief in Opposition,, <i>Appendix To Plaintiffs' Answering Brief In Opposition To Defendant's Motion For Partial Summary Judgment Of Invalidity Of The Asserted Aspar Claims (PA-1103 - PA-1143 FILED UNDER SEAL)</i> by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Exhibit PA-1103 - PA-1109 FILED UNDER SEAL, # <u>2</u> Exhibit PA-1110 - PA-1118 FILED UNDER SEAL, # <u>3</u> Exhibit PA-1119 - PA-1130 FILED UNDER SEAL, # <u>4</u> Exhibit PA-1131 - PA-1143, # <u>5</u> Certificate of Service)(Kraft, Denise) (Entered: 07/20/2010)
E648	NOTICE OF SERVICE of Documents Marked MEMC0782013 - MEMC0782178 by MEMC Electronic Materials Inc..(Rogowski, Patricia) (Entered: 07/21/2010)
E649	Letter to The Honorable Sue L. Robinson from Denise Seastone Kraft regarding Courtesy CD-ROM copies of: (1) Plaintiffs Answering Brief In Opposition To Defendants Motion For Partial Summary Judgment of Invalidity of The Asserted Aspar Claims and Appendix; and (2) Soitecs Brief In Opposition To Defendants Motion For Summary Judgment of Non-Infringement and Appendix. (Kraft, Denise) (Entered: 07/21/2010); SO ORDERED- re <u>238</u> STIPULATION To Amend Scheduling Order. ORDER- Setting Scheduling Order Deadlines (Reply Brief due 7/30/2010).(REFER TO STIPULATION FOR DETAILS). Signed by Judge Sue L. Robinson on 7/22/2010. (lid) (Entered: 07/22/2010)
E650	REDACTED VERSION of <u>241</u> Answering Brief in Opposition, to <i>Plaintiffs' Motion for Partial Summary Judgment that the Best Mode Requirement is Satisfied for the Claims of the '009 and '396 Patents</i> by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 07/26/2010)
E651	REDACTED VERSION of <u>249</u> Answering Brief in Opposition, to <i>Plaintiffs' Motion for Summary Judgment on the Infringement of U.S. Patent No. 5,834,812</i> by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 07/26/2010)
E652	REDACTED VERSION of <u>253</u> Answering Brief in Opposition, to <i>Plaintiffs' Motion for Partial Summary Judgment that the Aspar Patents Are Not Invalid for Inequitable Conduct</i> by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 07/26/2010)

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FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)		APPLICANT(S): MORICEAU, et al.

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E653	(Document too large to file in pdf format, will file at later date by Express Mail). REDACTED VERSION of <u>240</u> Appendix by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Appendix MA0932 - MA0985, # <u>2</u> Appendix MA0986 - MA1039.22, # <u>3</u> Appendix MA1040 - MA1144, # <u>4</u> Appendix MA1145 - MA1200, # <u>5</u> Appendix MA1201 - MA1265, # <u>6</u> Appendix MA1265.1 - MA1338, # <u>7</u> Appendix MA1339 - MA1547, # <u>8</u> Appendix MA1548 - MA1627, # <u>9</u> Appendix MA1628 - MA1693, # <u>10</u> Appendix MA1694 - MA1953, # <u>11</u> Appendix MA1954 - MA2127, # <u>12</u> Appendix MA2128 - MA2206, # <u>13</u> Appendix MA2207 - MA2253, # <u>14</u> Appendix MA2254 - MA2273, # <u>15</u> Appendix MA2274 - MA2333, # <u>16</u> Appendix MA2334 - MA2337, # <u>17</u> Appendix MA2338 - MA2342, # <u>18</u> Appendix MA2343 - MA2346, # <u>19</u> Appendix MA2347 - MA2351, # <u>20</u> Certificate of Service)(Rogowski, Patricia) (Entered: 07/26/2010)
E654	SEALED ANSWERING BRIEF in Opposition re <u>213</u> MOTION for Partial Summary Judgment <i>That the Best Mode Requirement is Satisfied for the Claims of the '009 and '396 Patents CORRECTED VERSION OF D.I. 241</i> filed by MEMC Electronic Materials Inc.. Reply Brief due date per Local Rules is 8/5/2010. (Rogowski, Patricia) (Entered: 07/26/2010)
E655	REDACTED VERSION of <u>261</u> Answering Brief in Opposition, to <i>Plaintiffs' Motion for Partial Summary Judgment that the Best Mode Requirement is Satisfied for the Claims of the '009 and '396 Patents (CORRECTED VERSION OF D.I. 241)</i> by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 07/26/2010)
E656	REDACTED VERSION of <u>250</u> Answering Brief in Opposition, to <i>Soitec's Brief in Opposition to Defendant's Motion For Summary Judgment of Non-Infringement by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA.</i> (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/26/2010)
E657	REDACTED VERSION of <u>247</u> Answering Brief in Opposition, to <i>Plaintiffs' Answering Brief In Opposition To Defendant's Motion For Partial Summary Judgment Of In validity Of The Asserted Aspar Claims</i> by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/26/2010)
E658	REDACTED VERSION of <u>254</u> Appendix, to <i>Appendix To Plaintiffs' Answering Brief In Opposition To Defendant's Motion For Partial Summary Judgment Of Invalidity Of The Asserted Aspar Claims (PA-1103 - PA-1143</i> by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA. (Kraft, Denise) (Entered: 07/26/2010)
E659	REDACTED VERSION of <u>251</u> Appendix, to <i>Appendix to Plaintiffs' Answering Brief in Opposition to Defendant's Motion For Summary Judgment of Non-Infringement by Commissariat a L'Energie Atomique, SOITEC Silicon On Insulator Technologies SA.</i> (Kraft, Denise) (Entered: 07/26/2010)
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E660	SEALED REPLY BRIEF re <u>187</u> MOTION for Partial Summary Judgment of <i>Invalidity of the Asserted Aspar Patent Claims</i> filed by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Certificate of Service)(Rogowski, Patricia) (Entered: 07/30/2010)
E661	REPLY BRIEF re <u>204</u> MOTION for Partial Summary Judgment <i>Plaintiffs' Motion For Partial Summary Judgment That The Certificate of Correction For the '396 Patent is Valid Reply Brief in Support of Plaintiffs' Motion For Partial Summary Judgment That The Certificate of Correction For the '396 Patent is Valid</i> filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/30/2010)
E662	SEALED APPENDIX re <u>267</u> Reply Brief in Support of <i>MEMC's Motion for Partial Summary Judgment of Invalidity of the Asserted Aspar Patent Claims</i> by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Table of Contents, # <u>2</u> Certificate of Service)(Rogowski, Patricia) (Entered: 07/30/2010)
E663	DECLARATION re <u>268</u> Reply Brief, <i>Declaration of Marcus T. Hall in Support of Reply Brief in Support of Plaintiffs' Motion For Partial Summary Judgment That The Certificate of Correction For the '396 Patent is Valid</i> by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Exhibit A, # <u>2</u> Certificate of Service)(Kraft, Denise) (Entered: 07/30/2010)
E664	SEALED REPLY BRIEF re <u>199</u> MOTION for Summary Judgment of <i>Non-Infringement</i> filed by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Certificate of Service)(Rogowski, Patricia) (Entered: 07/30/2010)
E665	APPENDIX re <u>268</u> Reply Brief, <i>Omnibus Appendix to Plaintiffs' Reply Briefs in Support of Plaintiffs' Daubert Motion and Motions For Partial Summary Judgment (PA-1192 - PA-1261)</i> by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Exhibit PA-1199 - PA-1204, # <u>2</u> Exhibit PA-1205 - PA-1206, # <u>3</u> Exhibit PA-1206.1, # <u>4</u> Exhibit PA-1231 - PA-1237, # <u>5</u> Exhibit PA-1238 - PA-1245, # <u>6</u> Exhibit PA-1246 - PA-1257, # <u>7</u> Exhibit PA-1258 - PA-1261, # <u>8</u> Certificate of Service)(Kraft, Denise) (Entered: 07/30/2010)
E666	SEALED APPENDIX re <u>271</u> Reply Brief in Support of <i>MEMC's Motion for Summary Judgment of Non-Infringement</i> by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Table of Contents, # <u>2</u> Certificate of Service)(Rogowski, Patricia) (Entered: 07/30/2010)

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EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E667	SEALED APPENDIX re <u>272</u> Appendix,, <i>Omnibus Appendix to Plaintiffs' Reply Briefs in Support of Plaintiffs' Daubert Motion and Motions For Partial Summary Judgment (PA-1192 - PA-1198 and PA-1207 - PA-1230 FILED UNDER SEAL)</i> by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Exhibit PA-1192 - PA-1198 (FILED UNDER SEAL), # <u>2</u> Exhibit PA-1207 - PA-1217 (FILED UNDER SEAL), # <u>3</u> Exhibit PA-1218 - PA-1230 (FILED UNDER SEAL), # <u>4</u> Certificate of Service)(Kraft, Denise) (Entered: 07/30/2010)
E668	REPLY BRIEF re <u>210</u> MOTION for Partial Summary Judgment <i>SOITEC's Motion For Partial Summary Judgment of Invalidity of United States Patent No. 5,834,812 For Lack of Enablement Reply Brief in Support of SOITEC's Motion For Partial Summary Judgment of Invalidity of United States Patent No. 5,834,812 For Lack of Enablement</i> filed by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/30/2010)
E669	REPLY BRIEF re <u>212</u> MOTION for Partial Summary Judgment <i>SOITEC's Motion For Partial Summary Judgment For Invalidity of Asserted Claims of United States Patent No. 5,834,812 in View of Prior Art Reply Brief in Support of SOITEC's Motion For Partial Summary Judgment For Invalidity of Asserted Claims of United States Patent No. 5,834,812 in View of Prior Art</i> filed by SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Exhibit A, # <u>2</u> Exhibit B, # <u>3</u> Certificate of Service)(Kraft, Denise) (Entered: 07/30/2010)
E670	REPLY BRIEF re <u>186</u> MOTION in <i>Limine SOITEC/CEA Parties' Motion to Exclude The Expert Report of Dr. Pascal Bellon and Any Related Testimony Reply Brief in Support of SOITEC/CEA Parties' Motion to Exclude The Expert Report of Dr. Pascal Bellon and Any Related Testimony</i> filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/30/2010)
E671	SEALED REPLY BRIEF re <u>197</u> SEALED MOTION for Summary Judgment <i>SOITEC/CEA Parties' Motion For Summary Judgment: Non-Infringement (FILED UNDER SEAL)</i> SEALED MOTION for Summary Judgment <i>SOITEC/CEA Parties' Motion For Summary Judgment: Non-Infringement (FILED UNDER SEAL)</i> Reply Brief in Support of <i>SOITEC/CEA Parties' Motion For Summary Judgment: Non-Infringement (FILED UNDER SEAL)</i> filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/30/2010)

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FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)	APPLICANT(S): MORICEAU, et al.	

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E672	SEALED REPLY BRIEF re <u>213</u> MOTION for Partial Summary Judgment <i>That the Best Mode Requirement is Satisfied for the Claims of the '009 and '396 Patents Reply Brief in Support of Plaintiffs' Motion for Partial Summary Judgment That the Best Mode Requirement is Satisfied for the Claims of the '009 and '396 Patents (FILED UNDER SEAL)</i> filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/30/2010)
E673	REPLY BRIEF re <u>202</u> MOTION for Partial Summary Judgment <i>SOITEC/CEA Parties Motion For Partial Summary Judgment That The Patents in Suit Satisfy The Written Description Requirement Reply Brief in Support of SOITEC/CEA Parties' Motion For Partial Summary Judgment That The Patents in Suit Satisfy The Written Description Requirement</i> filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/30/2010)
E674	SEALED REPLY BRIEF re <u>208</u> MOTION for Partial Summary Judgment <i>Plaintiffs' Motion For Partial Summary Judgment That The Bruel Patent Does Not Anticipate The Aspar Patents Reply Brief in Support of Plaintiffs' Motion For Partial Summary Judgment That The Bruel Patent Does Not Anticipate The Aspar Patents (FILED UNDER SEAL)</i> filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/30/2010)
E675	SEALED REPLY BRIEF re <u>206</u> MOTION for Partial Summary Judgment <i>SOITEC/CEA Parties' Motion For Partial Summary Judgment That The Aspar Patents Are Not Invalid For Inequitable Conduct Reply Brief in Support of SOITEC/CEA Parties' Motion For Partial Summary Judgment That The Aspar Patents Are Not Invalid For Inequitable Conduct (FILED UNDER SEAL)</i> filed by Commissariat a LEnergie Atomique, SOITEC Silicon On Insulator Technologies SA, SOITEC U.S.A., Inc.. (Attachments: # <u>1</u> Certificate of Service)(Kraft, Denise) (Entered: 07/30/2010)
E676	Letter to The Honorable Sue L. Robinson from Denise Seastone Kraft, Esq. regarding Courtesy CD-ROM copies of Plaintiffs' Reply to Daubert Motion and Motions for Partial Summary Judgment, and Plaintiffs' Omnibus Appendix to the Replies. (Kraft, Denise) (Entered: 08/02/2010)
E677	REDACTED VERSION of <u>269</u> Appendix, <i>TO REPLY BRIEF IN SUPPORT OF MEMC's MOTION FOR PARTIAL SUMMARY JUDGMENT OF INVALIDITY OF THE ASSERTED ASPAR PATENT CLAIMS</i> by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Appendix Table of Contents, # <u>2</u> Appendix MA2453_MA2479, # <u>3</u> Certificate of Service)(Rogowski, Patricia) (Entered: 08/03/2010)

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FORM PTO-1449	SERIAL NO. 10/565,621	CASE NO. 9905/37 (BIF116044/US)
LIST OF PATENTS AND PUBLICATIONS FOR APPLICANT'S INFORMATION DISCLOSURE STATEMENT	FILING DATE July 25, 2006	GROUP ART UNIT 2812
(use several sheets if necessary)	APPLICANT(S): MORICEAU, et al.	

EXAMINER INITIAL	OTHER ART – NON PATENT LITERATURE DOCUMENTS (Include name of author, title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date page(s), volume-issue number(s), publisher, city and/or country where published.
E678	REDACTED VERSION of <u>273</u> Appendix <i>REPLY BRIEF IN SUPPORT OF MEMC's MOTION FOR SUMMARY JUDGMENT OF NON-INFRINGEMENT</i> by MEMC Electronic Materials Inc.. (Attachments: # <u>1</u> Appendix Table of Contents, # <u>2</u> Appendix MA2352 - MA2361, # <u>3</u> Appendix MA2362 - MA2371, # <u>4</u> Appendix MA2372 - MA2381, # <u>5</u> Appendix MA2382 - MA2391, # <u>6</u> Appendix MA2392 - MA2399, # <u>7</u> Appendix MA2400 - MA2404, # <u>8</u> Appendix MA2405 - MA2422, # <u>9</u> Appendix MA2423 - MA2425, # <u>10</u> Appendix MA2426 - MA2427, # <u>11</u> Appendix MA2428 - MA2430, # <u>12</u> Appendix MA2431 - MA2440, # <u>13</u> Appendix MA2441 - MA2448, # <u>14</u> Appendix MA2449 - MA2452, # <u>15</u> Appendix MA2452.1 - MA2452.9, # <u>16</u> Certificate of Service)(Rogowski, Patricia) (Entered: 08/03/2010)
E679	Letter to The Honorable Sue L. Robinson from Patricia Smink Rogowski regarding CD-ROM copies of (1) MEMC's Claim Construction Briefing, (2) MEMC's Briefs in Support of MEMC's Motion for Summary Judgment, and (3) MEMC's Briefs in Opposition to Soitec's Summary Judgment Motions. (Rogowski, Patricia) (Entered: 08/03/2010)
E680	REDACTED VERSION of <u>267</u> Reply Brief <i>IN SUPPORT OF MEMC's MOTION FOR PARTIAL SUMMARY JUDGMENT OF INVALIDITY OF THE ASSERTED ASPAR PATENT CLAIMS</i> by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 08/03/2010)
E681	REDACTED VERSION of <u>271</u> Reply Brief <i>IN SUPPORT OF MEMC's MOTION FOR SUMMARY JUDGMENT OF NON-INFRINGEMENT</i> by MEMC Electronic Materials Inc.. (Rogowski, Patricia) (Entered: 08/03/2010)

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